



# CC2630 SimpleLink™ 6LoWPAN, ZigBee® Wireless MCU

## 1 Device Overview

### 1.1 Features

- Microcontroller
  - Powerful ARM® Cortex®-M3
  - EEMBC CoreMark® Score: 142
  - Up to 48-MHz Clock Speed
  - 128KB of In-System Programmable Flash
  - 8KB of SRAM for Cache
  - 20KB of Ultralow-Leakage SRAM
  - 2-Pin cJTAG and JTAG Debugging
  - Supports Over-The-Air Upgrade (OTA)
- Ultralow-Power Sensor Controller
  - Can Run Autonomous From the Rest of the System
  - 16-Bit Architecture
  - 2KB of Ultralow-Leakage SRAM for Code and Data
- Efficient Code Size Architecture, Placing Drivers, IEEE 802.15.4 MAC, and Bootloader in ROM
- RoHS-Compliant Packages
  - 4-mm × 4-mm RSM VQFN32 (10 GPIOs)
  - 5-mm × 5-mm RHB VQFN32 (15 GPIOs)
  - 7-mm × 7-mm RGZ VQFN48 (31 GPIOs)
- Peripherals
  - All Digital Peripheral Pins Can Be Routed to Any GPIO
  - Four General-Purpose Timer Modules (Eight 16-Bit or Four 32-Bit Timers, PWM Each)
  - 12-Bit ADC, 200-ksamples/s, 8-Channel Analog MUX
  - Continuous Time Comparator
  - Ultralow-Power Analog Comparator
  - Programmable Current Source
  - UART
  - 2× SSI (SPI, MICROWIRE, TI)
  - I2C
  - I2S
  - Real-Time Clock (RTC)
  - AES-128 Security Module
  - True Random Number Generator (TRNG)
  - 10, 15, or 31 GPIOs, Depending on Package Option
  - Support for Eight Capacitive-Sensing Buttons
  - Integrated Temperature Sensor
- External System
  - On-Chip internal DC-DC Converter
  - Very Few External Components
  - Seamless Integration With the SimpleLink™ CC2590 and CC2592 Range Extenders
  - Pin Compatible With the SimpleLink CC13xx in 4-mm × 4-mm and 5-mm × 5-mm VQFN Packages
- Low Power
  - Wide Supply Voltage Range
    - Normal Operation: 1.8 to 3.8 V
    - External Regulator Mode: 1.7 to 1.95 V
  - Active-Mode RX: 5.9 mA
  - Active-Mode TX at 0 dBm: 6.1 mA
  - Active-Mode TX at +5 dBm: 9.1 mA
  - Active-Mode MCU: 61 µA/MHz
  - Active-Mode MCU: 48.5 CoreMark/mA
  - Active-Mode Sensor Controller: 8.2 µA/MHz
  - Standby: 1 µA (RTC Running and RAM/CPU Retention)
  - Shutdown: 100 nA (Wake Up on External Events)
- RF Section
  - 2.4-GHz RF Transceiver Compatible With IEEE 802.15.4 PHY and MAC
  - Excellent Receiver Sensitivity (–100 dBm), Selectivity, and Blocking Performance
  - Link budget of 105 dB
  - Programmable Output Power up to +5 dBm
  - Single-Ended or Differential RF Interface
  - Suitable for Systems Targeting Compliance With Worldwide Radio Frequency Regulations
    - ETSI EN 300 328 (Europe)
    - EN 300 440 Class 2 (Europe)
    - FCC CFR47 Part 15 (US)
    - ARIB STD-T66 (Japan)
- Tools and Development Environment
  - Full-Feature and Low-Cost Development Kits
  - Multiple Reference Designs for Different RF Configurations
  - Packet Sniffer PC Software
  - Sensor Controller Studio
  - SmartRF™ Studio
  - SmartRF Flash Programmer 2
  - IAR Embedded Workbench® for ARM
  - Code Composer Studio™



## 1.2 Applications

- Home and Building Automation
- Lighting Control
- Alarm and Security
- Electronic Shelf Labeling
- Proximity Tags
- Wireless Sensor Networks
- Energy Harvesting, Batteryless Sensors, and Actuators
- Smart Grid

## 1.3 Description

The CC2630 device is a wireless MCU targeting ZigBee® and 6LoWPAN applications.

The device is a member of the CC26xx family of cost-effective, ultralow power, 2.4-GHz RF devices. Very low active RF and MCU current and low-power mode current consumption provide excellent battery lifetime and allow for operation on small coin cell batteries and in energy-harvesting applications.

The CC2630 device contains a 32-bit ARM Cortex-M3 processor that runs at 48 MHz as the main processor and a rich peripheral feature set that includes a unique ultralow power sensor controller. This sensor controller is ideal for interfacing external sensors and for collecting analog and digital data autonomously while the rest of the system is in sleep mode. Thus, the CC2630 device is ideal for battery-powered and energy harvesting end nodes in ZigBee and 6LoWPAN networks.

The IEEE 802.15.4 MAC is embedded into ROM and runs partly on an ARM Cortex-M0 processor. This architecture improves overall system performance and power consumption and frees up flash memory for the application.

The ZigBee stack is available free of charge from [www.ti.com](http://www.ti.com).

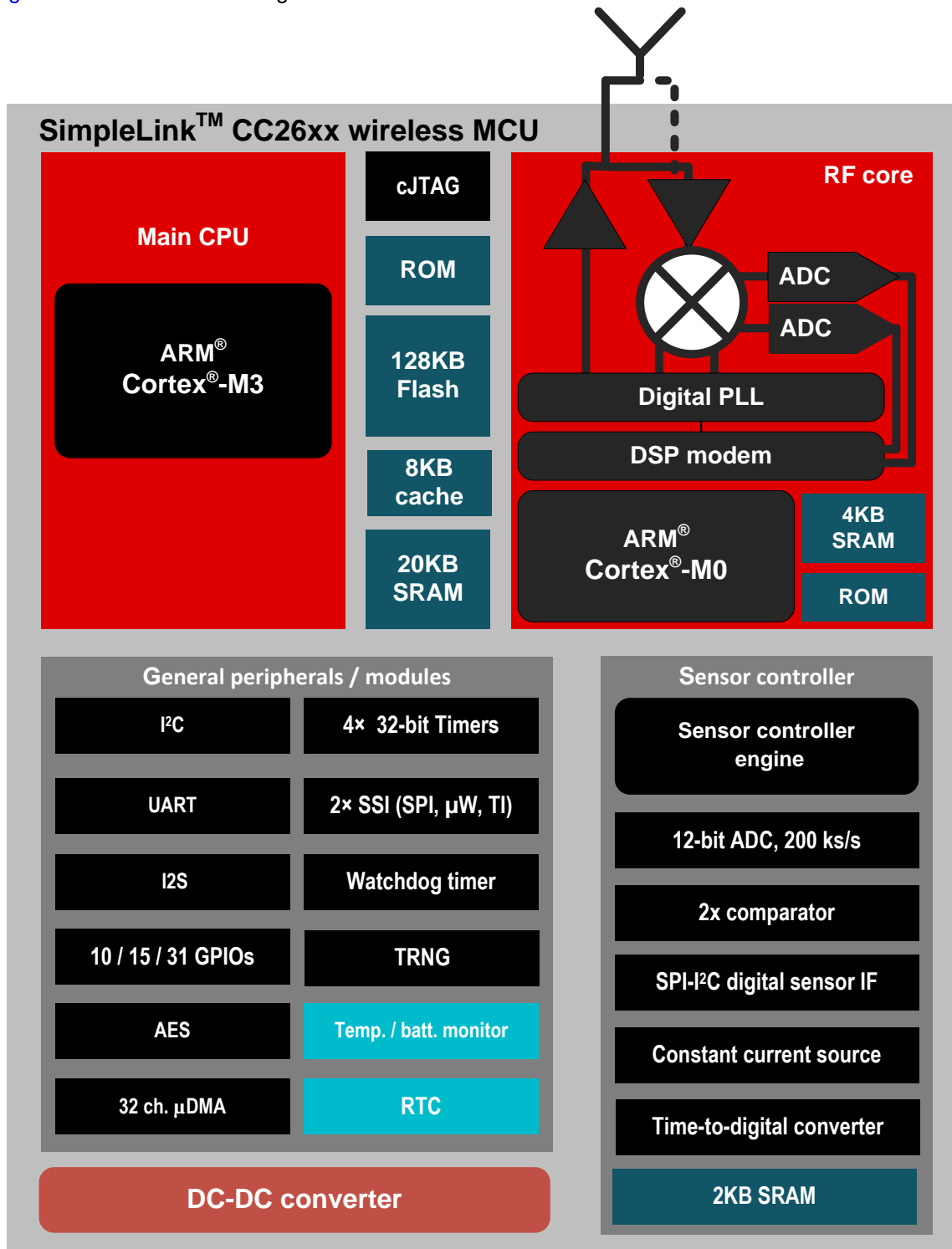
**Device Information<sup>(1)</sup>**

| PART NUMBER   | PACKAGE   | BODY SIZE (NOM)   |
|---------------|-----------|-------------------|
| CC2630F128RGZ | VQFN (48) | 7.00 mm × 7.00 mm |
| CC2630F128RHB | VQFN (32) | 5.00 mm × 5.00 mm |
| CC2630F128RSM | VQFN (32) | 4.00 mm × 4.00 mm |

(1) For more information, see [Section 9](#), *Mechanical Packaging and Orderable Information*.

## 1.4 Functional Block Diagram

Figure 1-1 shows a block diagram for the CC2630.



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**Figure 1-1. Block Diagram**

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## 2 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from October 15, 2015 to July 5, 2016   | Page               |
|---|--------------------|
| • Added split VDDS supply rail feature .....  | <a href="#">1</a>  |
| • Added 2-Mbps <i>Bluetooth</i> low energy.....   | <a href="#">1</a>  |
| • Added option for up to 80-Ω ESR when $C_L$ is 6 pF or lower .....   | <a href="#">16</a> |
| • Added motional inductance recommendation to the 24-MHz XOSC table .....   | <a href="#">16</a> |
| • Added tolerance for RCOSC_LF and RTC accuracy content .....   | <a href="#">17</a> |
| • Updated the Soc ADC internal voltage reference specification in <a href="#">Section 5.12</a> .....                | <a href="#">17</a> |
| • Moved all SSI parameters to <a href="#">Section 5.18</a> .....  | <a href="#">20</a> |
| • Added SPI timing parameters .....   | <a href="#">20</a> |
| • Added VOH and VOL min and max values for 4-mA and 8-mA load .....   | <a href="#">22</a> |
| • Added min and max values for VIH and VIL .....  | <a href="#">23</a> |
| • Added 0-dBm setting to the <i>TX Current Consumption vs Supply Voltage (VDDS)</i> graph .....                     | <a href="#">25</a> |
| • Changed <a href="#">Figure 5-11</a> , <i>Receive Mode Current vs Supply Voltage (VDDS)</i> .....                  | <a href="#">25</a> |
| • Added <a href="#">Figure 5-21</a> , <i>Supply Current vs Temperature</i> .....                                    | <a href="#">26</a> |
| • Added application circuit schematics and layout for 5XD and 4XS .....   | <a href="#">36</a> |
| Changes from February 21, 2015 to October 15, 2015  | Page               |
| • Removed RHB package option from CC2620 .....  | <a href="#">6</a>  |
| • Added motional inductance recommendation to the 24-MHz XOSC table .....   | <a href="#">16</a> |
| • Added SPI timing parameters .....   | <a href="#">20</a> |
| • Added VOH and VOL min and max values for 4-mA and 8-mA load .....   | <a href="#">22</a> |
| • Added min and max values for VIH and VIL .....  | <a href="#">23</a> |
| • Added <i>IEEE 802.15.4 Sensitivity vs Channel Frequency</i> .....   | <a href="#">25</a> |
| • Added <i>RF Output Power vs Channel Frequency</i> .....   | <a href="#">25</a> |
| • Added <a href="#">Figure 5-11</a> , <i>Receive Mode Current vs Supply Voltage (VDDS)</i> .....                    | <a href="#">25</a> |
| • Changed <a href="#">Figure 5-20</a> , <i>SoC ADC ENOB vs Sampling Frequency (Input Frequency = FS / 10)</i> ..... | <a href="#">26</a> |
| • Clarified Brown Out Detector status and functionality in the <i>Power Modes</i> table. ....                       | <a href="#">33</a> |
| • Added application circuit schematics and layout for 5XD and 4XS .....   | <a href="#">36</a> |

## 3 Device Comparison

**Table 3-1. Device Family Overview**

| DEVICE        | PHY SUPPORT                          | FLASH (KB) | RAM (KB) | GPIO       | PACKAGE <sup>(1)</sup> |
|---------------|--------------------------------------|------------|----------|------------|------------------------|
| CC2650F128xxx | Multi-Protocol <sup>(2)</sup>        | 128        | 20       | 31, 15, 10 | RGZ, RHB, RSM          |
| CC2640F128xxx | <i>Bluetooth</i> low energy (Normal) | 128        | 20       | 31, 15, 10 | RGZ, RHB, RSM          |
| CC2630F128xxx | IEEE 802.15.4 Zigbee/6LoWPAN)        | 128        | 20       | 31, 15, 10 | RGZ, RHB, RSM          |
| CC2620F128xxx | IEEE 802.15.4 (RF4CE)                | 128        | 20       | 31, 10     | RGZ, RSM               |

(1) Package designator replaces the xxx in device name to form a complete device name, RGZ is 7-mm × 7-mm VQFN48, RHB is 5-mm × 5-mm VQFN32, and RSM is 4-mm × 4-mm VQFN32.

(2) The CC2650 device supports all PHYs and can be reflashed to run all the supported standards.

### 3.1 Related Products

**Wireless Connectivity** The wireless connectivity portfolio offers a wide selection of low power RF solutions suitable for a broad range of application. The offerings range from fully customized solutions to turn key offerings with pre-certified hardware and software (protocol).

**Sub-1 GHz** Long-range, low power wireless connectivity solutions are offered in a wide range of Sub-1 GHz ISM bands.

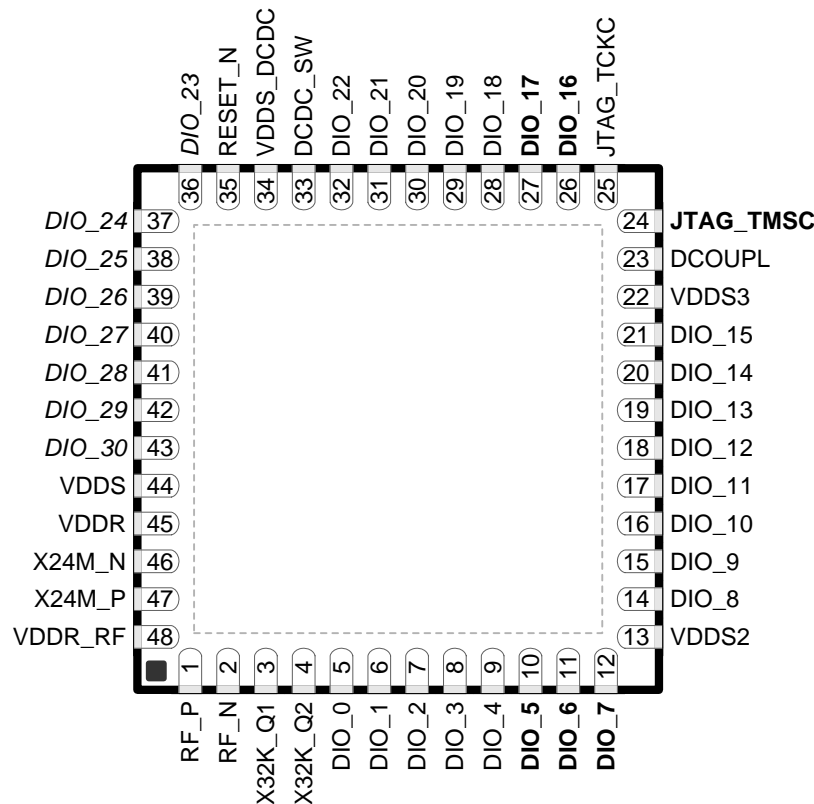
**Companion Products** Review products that are frequently purchased or used in conjunction with this product.

**SimpleLink™ CC2650 Wireless MCU LaunchPad™ Kit** The CC2650 LaunchPad kit brings easy Bluetooth® Smart connectivity to the LaunchPad kit ecosystem with the SimpleLink ultra-low power CC26xx family of devices. This LaunchPad kit also supports development for multi-protocol support for the SimpleLink multi-standard CC2650 wireless MCU and the rest of CC26xx family of products: CC2630 wireless MCU for ZigBee®/6LoWPAN and CC2640 wireless MCU for *Bluetooth*® Smart.

**Reference Designs for CC2630** TI Designs Reference Design Library is a robust reference design library spanning analog, embedded processor and connectivity. Created by TI experts to help you jump-start your system design, all TI Designs include schematic or block diagrams, BOMs and design files to speed your time to market. Search and download designs at [ti.com/tidesigns](http://ti.com/tidesigns).

## 4 Terminal Configuration and Functions

### 4.1 Pin Diagram – RGZ Package



Note: I/O pins marked in **bold** have high drive capabilities. I/O pins marked in *italics* have analog capabilities.

**Figure 4-1. RGZ Package**  
**48-Pin VQFN**  
**(7-mm × 7-mm) Pinout, 0.5-mm Pitch**

### 4.2 Signal Descriptions – RGZ Package

**Table 4-1. Signal Descriptions – RGZ Package**

| NAME    | NO. | TYPE        | DESCRIPTION   |
|---------|-----|-------------|---|
| DCDC_SW | 33  | Power       | Output from internal DC-DC <sup>(1)</sup>                           |
| DCOUPPL | 23  | Power       | 1.27-V regulated digital-supply decoupling capacitor <sup>(2)</sup> |
| DIO_0   | 5   | Digital I/O | GPIO, Sensor Controller   |
| DIO_1   | 6   | Digital I/O | GPIO, Sensor Controller   |
| DIO_2   | 7   | Digital I/O | GPIO, Sensor Controller   |
| DIO_3   | 8   | Digital I/O | GPIO, Sensor Controller   |
| DIO_4   | 9   | Digital I/O | GPIO, Sensor Controller   |
| DIO_5   | 10  | Digital I/O | GPIO, Sensor Controller, high-drive capability                      |
| DIO_6   | 11  | Digital I/O | GPIO, Sensor Controller, high-drive capability                      |
| DIO_7   | 12  | Digital I/O | GPIO, Sensor Controller, high-drive capability                      |
| DIO_8   | 14  | Digital I/O | GPIO  |
| DIO_9   | 15  | Digital I/O | GPIO  |
| DIO_10  | 16  | Digital I/O | GPIO  |

(1) See technical reference manual (listed in [Section 8.3](#)) for more details.

(2) Do not supply external circuitry from this pin.

**Table 4-1. Signal Descriptions – RGZ Package (continued)**

| NAME      | NO. | TYPE               | DESCRIPTION   |
|-----------|-----|--------------------|---|
| DIO_11    | 17  | Digital I/O        | GPIO  |
| DIO_12    | 18  | Digital I/O        | GPIO  |
| DIO_13    | 19  | Digital I/O        | GPIO  |
| DIO_14    | 20  | Digital I/O        | GPIO  |
| DIO_15    | 21  | Digital I/O        | GPIO  |
| DIO_16    | 26  | Digital I/O        | GPIO, JTAG_TDO, high-drive capability   |
| DIO_17    | 27  | Digital I/O        | GPIO, JTAG_TDI, high-drive capability   |
| DIO_18    | 28  | Digital I/O        | GPIO  |
| DIO_19    | 29  | Digital I/O        | GPIO  |
| DIO_20    | 30  | Digital I/O        | GPIO  |
| DIO_21    | 31  | Digital I/O        | GPIO  |
| DIO_22    | 32  | Digital I/O        | GPIO  |
| DIO_23    | 36  | Digital/Analog I/O | GPIO, Sensor Controller, Analog   |
| DIO_24    | 37  | Digital/Analog I/O | GPIO, Sensor Controller, Analog   |
| DIO_25    | 38  | Digital/Analog I/O | GPIO, Sensor Controller, Analog   |
| DIO_26    | 39  | Digital/Analog I/O | GPIO, Sensor Controller, Analog   |
| DIO_27    | 40  | Digital/Analog I/O | GPIO, Sensor Controller, Analog   |
| DIO_28    | 41  | Digital/Analog I/O | GPIO, Sensor Controller, Analog   |
| DIO_29    | 42  | Digital/Analog I/O | GPIO, Sensor Controller, Analog   |
| DIO_30    | 43  | Digital/Analog I/O | GPIO, Sensor Controller, Analog   |
| JTAG_TMSC | 24  | Digital I/O        | JTAG TMS, high-drive capability   |
| JTAG_TCKC | 25  | Digital I/O        | JTAG TCKC   |
| RESET_N   | 35  | Digital input      | Reset, active-low. No internal pullup.  |
| RF_P      | 1   | RF I/O             | Positive RF input signal to LNA during RX<br>Positive RF output signal to PA during TX  |
| RF_N      | 2   | RF I/O             | Negative RF input signal to LNA during RX<br>Negative RF output signal to PA during TX  |
| VDDR      | 45  | Power              | 1.7-V to 1.95-V supply, typically connect to output of internal DC-DC <sup>(2)(3)</sup> |
| VDDR_RF   | 48  | Power              | 1.7-V to 1.95-V supply, typically connect to output of internal DC-DC <sup>(2)(4)</sup> |
| VDDS      | 44  | Power              | 1.8-V to 3.8-V main chip supply <sup>(1)</sup>  |
| VDDS2     | 13  | Power              | 1.8-V to 3.8-V DIO supply <sup>(1)</sup>  |
| VDDS3     | 22  | Power              | 1.8-V to 3.8-V DIO supply <sup>(1)</sup>  |
| VDDS_DCDC | 34  | Power              | 1.8-V to 3.8-V DC-DC supply   |
| X32K_Q1   | 3   | Analog I/O         | 32-kHz crystal oscillator pin 1   |
| X32K_Q2   | 4   | Analog I/O         | 32-kHz crystal oscillator pin 2   |
| X24M_N    | 46  | Analog I/O         | 24-MHz crystal oscillator pin 1   |
| X24M_P    | 47  | Analog I/O         | 24-MHz crystal oscillator pin 2   |
| EGP       |     | Power              | Ground – Exposed Ground Pad   |

(3) If internal DC-DC is not used, this pin is supplied internally from the main LDO.

(4) If internal DC-DC is not used, this pin must be connected to VDDR for supply from the main LDO.



Pin diagram of the STM32F405RG microcontroller in a 48-pin LQFP package. The pins are numbered 1 to 48. The pin functions are:

- Pin 1: RF\_P
- Pin 2: RF\_N
- Pin 3: RX\_TX
- Pin 4: X32K\_Q1
- Pin 5: X32K\_Q2
- Pin 6: DIO\_0
- Pin 7: DIO\_1
- Pin 8: DIO\_2
- Pin 9: DIO\_3
- Pin 10: DIO\_4
- Pin 11: VDDSD2
- Pin 12: DCOUPL
- Pin 13: JTAG\_TMS
- Pin 14: JTAG\_TCK
- Pin 15: DIO\_5
- Pin 16: DIO\_6
- Pin 17: CDC\_SW
- Pin 18: VDDSDCDC
- Pin 19: RESET\_N
- Pin 20: DIO\_7
- Pin 21: DIO\_8
- Pin 22: DIO\_9
- Pin 23: DIO\_10
- Pin 24: DIO\_11
- Pin 25: DIO\_12
- Pin 26: DIO\_13
- Pin 27: DIO\_14
- Pin 28: VDDSD
- Pin 29: VDDR
- Pin 30: X24M\_N
- Pin 31: X24M\_P
- Pin 32: VDDR\_RF

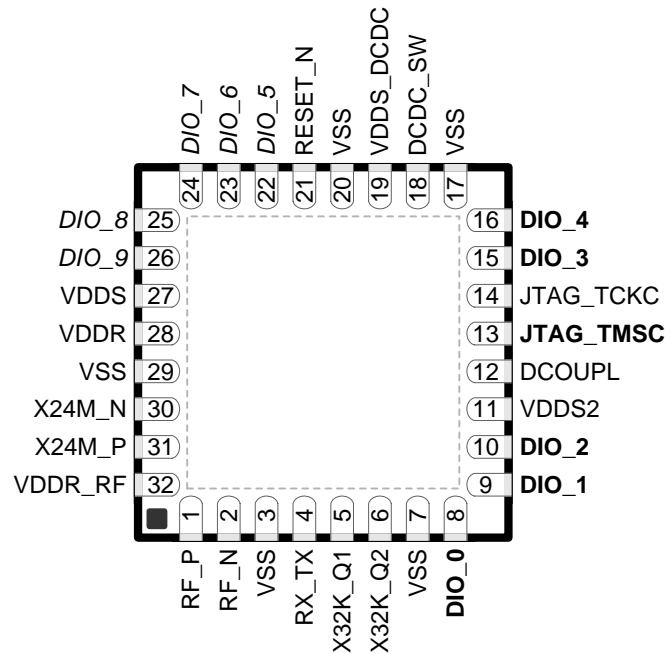
**Table 4-2. Signal Descriptions – RHB Package (continued)**

| NAME      | NO. | TYPE          | DESCRIPTION  |
|-----------|-----|---------------|--|
| RESET_N   | 19  | Digital input | Reset, active-low. No internal pullup.   |
| RF_N      | 2   | RF I/O        | Negative RF input signal to LNA during RX<br>Negative RF output signal to PA during TX   |
| RF_P      | 1   | RF I/O        | Positive RF input signal to LNA during RX<br>Positive RF output signal to PA during TX   |
| RX_TX     | 3   | RF I/O        | Optional bias pin for the RF LNA   |
| VDDR      | 29  | Power         | 1.7-V to 1.95-V supply, typically connect to output of internal DC-DC <sup>(3)</sup> (2) |
| VDDR_RF   | 32  | Power         | 1.7-V to 1.95-V supply, typically connect to output of internal DC-DC <sup>(2)</sup> (4) |
| VDDS      | 28  | Power         | 1.8-V to 3.8-V main chip supply <sup>(1)</sup>   |
| VDDS2     | 11  | Power         | 1.8-V to 3.8-V GPIO supply <sup>(1)</sup>  |
| VDDS_DCDC | 18  | Power         | 1.8-V to 3.8-V DC-DC supply  |
| X32K_Q1   | 4   | Analog I/O    | 32-kHz crystal oscillator pin 1  |
| X32K_Q2   | 5   | Analog I/O    | 32-kHz crystal oscillator pin 2  |
| X24M_N    | 30  | Analog I/O    | 24-MHz crystal oscillator pin 1  |
| X24M_P    | 31  | Analog I/O    | 24-MHz crystal oscillator pin 2  |
| EGP       |     | Power         | Ground – Exposed Ground Pad  |

(3) If internal DC-DC is not used, this pin is supplied internally from the main LDO.

(4) If internal DC-DC is not used, this pin must be connected to VDDR for supply from the main LDO.

## 4.5 Pin Diagram – RSM Package



Note: I/O pins marked in **bold** have high drive capabilities. I/O pins marked in *italics* have analog capabilities.

**Figure 4-3. RSM Package**  
**32-Pin VQFN**  
**(4-mm × 4-mm) Pinout, 0.4-mm Pitch**

## 4.6 Signal Descriptions – RSM Package

**Table 4-3. Signal Descriptions – RSM Package**

| NAME      | NO. | TYPE               | DESCRIPTION  |
|-----------|-----|--------------------|--|
| DCDC_SW   | 18  | Power              | Output from internal DC-DC. <sup>(1)</sup> Tie to ground for external regulator mode (1.7-V to 1.95-V operation) |
| DCOUPPL   | 12  | Power              | 1.27-V regulated digital-supply decoupling capacitor <sup>(2)</sup>  |
| DIO_0     | 8   | Digital I/O        | GPIO, Sensor Controller, high-drive capability   |
| DIO_1     | 9   | Digital I/O        | GPIO, Sensor Controller, high-drive capability   |
| DIO_2     | 10  | Digital I/O        | GPIO, Sensor Controller, high-drive capability   |
| DIO_3     | 15  | Digital I/O        | GPIO, High drive capability, JTAG_TDO  |
| DIO_4     | 16  | Digital I/O        | GPIO, High drive capability, JTAG_TDI  |
| DIO_5     | 22  | Digital/Analog I/O | GPIO, Sensor Controller, Analog  |
| DIO_6     | 23  | Digital/Analog I/O | GPIO, Sensor Controller, Analog  |
| DIO_7     | 24  | Digital/Analog I/O | GPIO, Sensor Controller, Analog  |
| DIO_8     | 25  | Digital/Analog I/O | GPIO, Sensor Controller, Analog  |
| DIO_9     | 26  | Digital/Analog I/O | GPIO, Sensor Controller, Analog  |
| JTAG_TMSC | 13  | Digital I/O        | JTAG TMSC  |
| JTAG_TCKC | 14  | Digital I/O        | JTAG TCKC  |
| RESET_N   | 21  | Digital Input      | Reset, active-low. No internal pullup.   |
| RF_N      | 2   | RF I/O             | Negative RF input signal to LNA during RX<br>Negative RF output signal to PA during TX                           |
| RF_P      | 1   | RF I/O             | Positive RF input signal to LNA during RX<br>Positive RF output signal to PA during TX                           |

(1) See technical reference manual (listed in [Section 8.3](#)) for more details.

(2) Do not supply external circuitry from this pin.

**Table 4-3. Signal Descriptions – RSM Package (continued)**

| NAME      | NO.              | TYPE       | DESCRIPTION   |
|-----------|------------------|------------|---|
| RX_TX     | 4                | RF I/O     | Optional bias pin for the RF LNA  |
| VDDR      | 28               | Power      | 1.7-V to 1.95-V supply, typically connect to output of internal DC-DC. <sup>(2)(3)</sup>            |
| VDDR_RF   | 32               | Power      | 1.7-V to 1.95-V supply, typically connect to output of internal DC-DC <sup>(2)(4)</sup>             |
| VDDS      | 27               | Power      | 1.8-V to 3.8-V main chip supply <sup>(1)</sup>  |
| VDDS2     | 11               | Power      | 1.8-V to 3.8-V GPIO supply <sup>(1)</sup>   |
| VDDS_DCDC | 19               | Power      | 1.8-V to 3.8-V DC-DC supply. Tie to ground for external regulator mode (1.7-V to 1.95-V operation). |
| VSS       | 3, 7, 17, 20, 29 | Power      | Ground  |
| X32K_Q1   | 5                | Analog I/O | 32-kHz crystal oscillator pin 1   |
| X32K_Q2   | 6                | Analog I/O | 32-kHz crystal oscillator pin 2   |
| X24M_N    | 30               | Analog I/O | 24-MHz crystal oscillator pin 1   |
| X24M_P    | 31               | Analog I/O | 24-MHz crystal oscillator pin 2   |
| EGP       |                  | Power      | Ground – Exposed Ground Pad   |

(3) If internal DC-DC is not used, this pin is supplied internally from the main LDO.

(4) If internal DC-DC is not used, this pin must be connected to VDDR for supply from the main LDO.

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)(2)</sup>

|   |  | MIN  | MAX                 | UNIT |
|---|--|------|---------------------|------|
| Supply voltage (VDD, VDD2, and VDD3)                                    | VDD supplied by internal DC-DC regulator or internal GLDO. VDD_DCDC connected to VDD on PCB. | −0.3 | 4.1                 | V    |
| Supply voltage (VDD <sup>(3)</sup> and VDD)                             | External regulator mode (VDD and VDD pins connected on PCB)                                  | −0.3 | 2.25                | V    |
| Voltage on any digital pin <sup>(4)(5)</sup>                            |  | −0.3 | VDDx + 0.3, max 4.1 | V    |
| Voltage on crystal oscillator pins, X32K_Q1, X32K_Q2, X24M_N and X24M_P |  | −0.3 | VDD + 0.3, max 2.25 | V    |
| Voltage on ADC input (V <sub>in</sub> )                                 | Voltage scaling enabled  | −0.3 | VDD                 | V    |
|   | Voltage scaling disabled, internal reference   | −0.3 | 1.49                |      |
|   | Voltage scaling disabled, VDD as reference   | −0.3 | VDD / 2.9           |      |
| Input RF level  |  |      | 5                   | dBm  |
| T <sub>stg</sub>  | Storage temperature  | −40  | 150                 | °C   |

(1) All voltage values are with respect to ground, unless otherwise noted.

(2) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(3) In external regulator mode, VDD2 and VDD3 must be at the same potential as VDD.

(4) Including analog-capable DIO.

(5) Each pin is referenced to a specific VDDx (VDD, VDD2 or VDD3). For a pin-to-VDD mapping table, see [Table 6-3](#).

### 5.2 ESD Ratings

|                  |   |  | VALUE       | UNIT  |   |
|------------------|---|--|-------------|-------|---|
| V <sub>ESD</sub> | Electrostatic discharge (ESD) performance | Human body model (HBM), per ANSI/ESDA/JEDEC JS001 <sup>(1)</sup> | All pins    | ±2500 | V |
|                  |   | Charged device model (CDM), per JESD22-C101 <sup>(2)</sup>       | RF pins     | ±750  |   |
|                  |   |  | Non-RF pins | ±750  |   |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|   |   | MIN                | MAX  | UNIT |
|---|---|--------------------|------|------|
| Ambient temperature range                                       |   | −40                | 85   | °C   |
| Operating supply voltage (VDD and VDD), external regulator mode | For operation in 1.8-V systems (VDD and VDD pins connected on PCB, internal DC-DC cannot be used)             | 1.7                | 1.95 | V    |
| Operating supply voltage VDD                                    | For operation in battery-powered and 3.3-V systems (internal DC-DC can be used to minimize power consumption) | 1.8                | 3.8  | V    |
| Operating supply voltages VDD2 and VDD3                         |   | 0.7 × VDD, min 1.8 | 3.8  | V    |

## 5.4 Power Consumption Summary

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DD5}} = 3.0\text{ V}$  with internal DC-DC converter, unless otherwise noted.

| PARAMETER   |                          | TEST CONDITIONS   | MIN                 | TYP | MAX | UNIT |
|---|--------------------------|---|---------------------|-----|-----|------|
| I <sub>core</sub>   | Core current consumption | Reset. RESET_N pin asserted or VDD5 below Power-on-Reset threshold            | 100                 |     | nA  |      |
|   |                          | Shutdown. No clocks running, no retention                                     | 150                 |     |     |      |
|   |                          | Standby. With RTC, CPU, RAM and (partial) register retention. RCOSC_LF        | 1                   |     | μA  |      |
|   |                          | Standby. With RTC, CPU, RAM and (partial) register retention. XOSC_LF         | 1.2                 |     |     |      |
|   |                          | Standby. With Cache, RTC, CPU, RAM and (partial) register retention. RCOSC_LF | 2.5                 |     |     |      |
|   |                          | Standby. With Cache, RTC, CPU, RAM and (partial) register retention. XOSC_LF  | 2.7                 |     |     |      |
|   |                          | Idle. Supply Systems and RAM powered.   | 550                 |     |     |      |
|   |                          | Active. Core running CoreMark   | 1.45 mA + 31 μA/MHz |     | mA  |      |
|   |                          | Radio RX <sup>(1)</sup>   | 5.9                 |     |     |      |
|   |                          | Radio RX <sup>(2)</sup>   | 6.1                 |     |     |      |
|   |                          | Radio TX, 0-dBm output power <sup>(1)</sup>                                   | 6.1                 |     |     |      |
|   |                          | Radio TX, 5-dBm output power <sup>(2)</sup>                                   | 9.1                 |     |     |      |
| Peripheral Current Consumption (Adds to core current I <sub>core</sub> for each peripheral unit activated) <sup>(3)</sup> |                          |   |                     |     |     |      |
| I <sub>peri</sub>   | Peripheral power domain  | Delta current with domain enabled   | 20                  |     | μA  |      |
|   | Serial power domain      | Delta current with domain enabled   | 13                  |     | μA  |      |
|   | RF Core                  | Delta current with power domain enabled, clock enabled, RF core idle          | 237                 |     | μA  |      |
|   | μDMA                     | Delta current with clock enabled, module idle                                 | 130                 |     | μA  |      |
|   | Timers                   | Delta current with clock enabled, module idle                                 | 113                 |     | μA  |      |
|   | I <sup>2</sup> C         | Delta current with clock enabled, module idle                                 | 12                  |     | μA  |      |
|   | I2S                      | Delta current with clock enabled, module idle                                 | 36                  |     | μA  |      |
|   | SSI                      | Delta current with clock enabled, module idle                                 | 93                  |     | μA  |      |
|   | UART                     | Delta current with clock enabled, module idle                                 | 164                 |     | μA  |      |

(1) Single-ended RF mode is optimized for size and power consumption. Measured on CC2650EM-4XS.

(2) Differential RF mode is optimized for RF performance. Measured on CC2650EM-5XD.

(3)  $I_{\text{peri}}$  is not supported in Standby or Shutdown.

## 5.5 General Characteristics

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DD5}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                                   | TEST CONDITIONS                          | MIN | TYP  | MAX | UNIT          |
|---|--|-----|------|-----|---------------|
| <b>FLASH MEMORY</b>                         |  |     |      |     |               |
| Supported flash erase cycles before failure |  | 100 |      |     | k Cycles      |
| Flash page/sector erase current             | Average delta current                    |     | 12.6 |     | mA            |
| Flash page/sector size                      |  |     | 4    |     | KB            |
| Flash write current                         | Average delta current, 4 bytes at a time |     | 8.15 |     | mA            |
| Flash page/sector erase time <sup>(1)</sup> |  |     | 8    |     | ms            |
| Flash write time <sup>(1)</sup>             | 4 bytes at a time                        |     | 8    |     | $\mu\text{s}$ |

(1) This number is dependent on Flash aging and will increase over time and erase cycles.

## 5.6 IEEE 802.15.4 (Offset Q-PSK DSSS, 250 kbps) – RX

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER  | TEST CONDITIONS  | MIN | TYP     | MAX | UNIT |
|--|--|-----|---------|-----|------|
| Receiver sensitivity                                       | Differential mode. Measured at the CC2650EM-5XD SMA connector, PER = 1%  |     | –100    |     | dBm  |
| Receiver sensitivity                                       | Single-ended mode. Measured on CC2650EM-4XS, at the SMA connector, PER = 1%  |     | –97     |     | dBm  |
| Receiver saturation  | Measured at the CC2650EM-5XD SMA connector, PER = 1%   |     | +4      |     | dBm  |
| Adjacent channel rejection                                 | Wanted signal at –82 dBm, modulated interferer at $\pm 5\text{ MHz}$ , PER = 1%  |     | 39      |     | dB   |
| Alternate channel rejection                                | Wanted signal at –82 dBm, modulated interferer at $\pm 10\text{ MHz}$ , PER = 1%   |     | 52      |     | dB   |
| Channel rejection, $\pm 15\text{ MHz}$ or more             | Wanted signal at –82 dBm, undesired signal is IEEE 802.15.4 modulated channel, stepped through all channels 2405 to 2480 MHz, PER = 1%   |     | 57      |     | dB   |
| Blocking and desensitization, 5 MHz from upper band edge   | Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%   |     | 64      |     | dB   |
| Blocking and desensitization, 10 MHz from upper band edge  | Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%   |     | 64      |     | dB   |
| Blocking and desensitization, 20 MHz from upper band edge  | Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%   |     | 65      |     | dB   |
| Blocking and desensitization, 50 MHz from upper band edge  | Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%   |     | 68      |     | dB   |
| Blocking and desensitization, –5 MHz from lower band edge  | Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%   |     | 63      |     | dB   |
| Blocking and desensitization, –10 MHz from lower band edge | Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%   |     | 63      |     | dB   |
| Blocking and desensitization, –20 MHz from lower band edge | Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%   |     | 65      |     | dB   |
| Blocking and desensitization, –50 MHz from lower band edge | Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%   |     | 67      |     | dB   |
| Spurious emissions, 30 MHz to 1000 MHz                     | Conducted measurement in a 50- $\Omega$ single-ended load. Suitable for systems targeting compliance with EN 300 328, EN 300 440 class 2, FCC CFR47, Part 15 and ARIB STD-T-66 |     | –71     |     | dBm  |
| Spurious emissions, 1 GHz to 12.75 GHz                     | Conducted measurement in a 50 $\Omega$ single-ended load. Suitable for systems targeting compliance with EN 300 328, EN 300 440 class 2, FCC CFR47, Part 15 and ARIB STD-T-66  |     | –62     |     | dBm  |
| Frequency error tolerance                                  | Difference between the incoming carrier frequency and the internally generated carrier frequency   |     | >200    |     | ppm  |
| Symbol rate error tolerance                                | Difference between incoming symbol rate and the internally generated symbol rate   |     | >1000   |     | ppm  |
| RSSI dynamic range   |  |     | 100     |     | dB   |
| RSSI accuracy  |  |     | $\pm 4$ |     | dB   |

## 5.7 IEEE 802.15.4 (Offset Q-PSK DSSS, 250 kbps) – TX

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                     | TEST CONDITIONS   | MIN | TYP | MAX | UNIT |
|-------------------------------|---|-----|-----|-----|------|
| Output power, highest setting | Delivered to a single-ended 50- $\Omega$ load through a balun           |     | 5   |     | dBm  |
| Output power, highest setting | Measured on CC2650EM-4XS, delivered to a single-ended 50- $\Omega$ load |     | 2   |     | dBm  |
| Output power, lowest setting  | Delivered to a single-ended 50- $\Omega$ load through a balun           |     | –21 |     | dBm  |
| Error vector magnitude        | At maximum output power   |     | 2%  |     |      |

## IEEE 802.15.4 (Offset Q-PSK DSSS, 250 kbps) – TX (continued)

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DD}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                               | TEST CONDITIONS  | MIN | TYP | MAX | UNIT |
|---|--|-----|-----|-----|------|
| Spurious emission conducted measurement | f < 1 GHz, outside restricted bands  |     | –43 |     | dBm  |
|   | f < 1 GHz, restricted bands ETSI   |     | –65 |     |      |
|   | f < 1 GHz, restricted bands FCC  |     | –76 |     |      |
|   | f > 1 GHz, including harmonics   |     | –46 |     |      |
|   | Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan) |     |     |     |      |

## 5.8 24-MHz Crystal Oscillator (XOSC\_HF)

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DD}} = 3.0\text{ V}$ , unless otherwise noted.<sup>(1)</sup>

| PARAMETER                                       | TEST CONDITIONS                                | MIN | TYP                             | MAX | UNIT          |
|---|--|-----|---------------------------------|-----|---------------|
| ESR Equivalent series resistance <sup>(2)</sup> | $6\text{ pF} < C_L \leq 9\text{ pF}$           |     | 20                              | 60  | $\Omega$      |
| ESR Equivalent series resistance <sup>(2)</sup> | $5\text{ pF} < C_L \leq 6\text{ pF}$           |     |                                 | 80  | $\Omega$      |
| $L_M$ Motional inductance <sup>(2)</sup>        | Relates to load capacitance ( $C_L$ in Farads) |     | $< 1.6 \times 10^{-24} / C_L^2$ |     | H             |
| $C_L$ Crystal load capacitance <sup>(2)</sup>   |  | 5   |                                 | 9   | pF            |
| Crystal frequency <sup>(2)(3)</sup>             |  |     | 24                              |     | MHz           |
| Crystal frequency tolerance <sup>(2)(4)</sup>   |  | –40 |                                 | 40  | ppm           |
| Start-up time <sup>(3)(5)</sup>                 |  |     | 150                             |     | $\mu\text{s}$ |

(1) Probing or otherwise stopping the XTAL while the DC-DC converter is enabled may cause permanent damage to the device.

(2) The crystal manufacturer's specification must satisfy this requirement

(3) Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DD}} = 3.0\text{ V}$

(4) Includes initial tolerance of the crystal, drift over temperature, ageing and frequency pulling due to incorrect load capacitance. As per IEEE 802.15.4 specification.

(5) Kick-started based on a temperature and aging compensated RCOSC\_HF using precharge injection.

## 5.9 32.768-kHz Crystal Oscillator (XOSC\_LF)

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DD}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                                       | TEST CONDITIONS | MIN | TYP    | MAX | UNIT       |
|---|-----------------|-----|--------|-----|------------|
| Crystal frequency <sup>(1)</sup>                |                 |     | 32.768 |     | kHz        |
| ESR Equivalent series resistance <sup>(1)</sup> |                 |     | 30     | 100 | k $\Omega$ |
| $C_L$ Crystal load capacitance <sup>(1)</sup>   |                 | 6   |        | 12  | pF         |

(1) The crystal manufacturer's specification must satisfy this requirement



## 5.10 48-MHz RC Oscillator (RCOSC\_HF)

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DD5}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                                    | TEST CONDITIONS | MIN | TYP          | MAX | UNIT          |
|--|-----------------|-----|--------------|-----|---------------|
| Frequency                                    |                 |     | 48           |     | MHz           |
| Uncalibrated frequency accuracy              |                 |     | $\pm 1\%$    |     |               |
| Calibrated frequency accuracy <sup>(1)</sup> |                 |     | $\pm 0.25\%$ |     |               |
| Start-up time                                |                 |     | 5            |     | $\mu\text{s}$ |

(1) Accuracy relative to the calibration source (XOSC\_HF).

## 5.11 32-kHz RC Oscillator (RCOSC\_LF)

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DD5}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                           | TEST CONDITIONS | MIN | TYP  | MAX | UNIT                  |
|-------------------------------------|-----------------|-----|------|-----|-----------------------|
| Calibrated frequency <sup>(1)</sup> |                 |     | 32.8 |     | kHz                   |
| Temperature coefficient             |                 |     | 50   |     | ppm/ $^\circ\text{C}$ |

(1) The frequency accuracy of the Real Time Clock (RTC) is not directly dependent on the frequency accuracy of the 32-kHz RC Oscillator. The RTC can be calibrated to an accuracy within  $\pm 500$  ppm of 32.768 kHz by measuring the frequency error of RCOSC\_LF relative to XOSC\_HF and compensating the RTC tick speed. The procedure is explained in [Running Bluetooth® Low Energy on CC2640 Without 32 kHz Crystal](#).

## 5.12 ADC Characteristics

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DD5}} = 3.0\text{ V}$  and voltage scaling enabled, unless otherwise noted.<sup>(1)</sup>

| PARAMETER  | TEST CONDITIONS  | MIN | TYP     | MAX  | UNIT |
|--|--|-----|---------|------|------|
| Input voltage range                              |  | 0   |         | VDD5 | V    |
| Resolution                                       |  |     | 12      |      | Bits |
| Sample rate                                      |  |     |         | 200  | ksps |
| Offset   | Internal 4.3-V equivalent reference <sup>(2)</sup>   |     | 2       |      | LSB  |
| Gain error                                       | Internal 4.3-V equivalent reference <sup>(2)</sup>   |     | 2.4     |      | LSB  |
| DNL <sup>(3)</sup> Differential nonlinearity     |  |     | $> -1$  |      | LSB  |
| INL <sup>(4)</sup> Integral nonlinearity         |  |     | $\pm 3$ |      | LSB  |
| ENOB Effective number of bits                    | Internal 4.3-V equivalent reference <sup>(2)</sup> , 200 ksps, 9.6-kHz input tone                    |     | 9.8     |      | Bits |
|  | VDD5 as reference, 200 ksps, 9.6-kHz input tone  |     | 10      |      |      |
|  | Internal 1.44-V reference, voltage scaling disabled, 32 samples average, 200 ksps, 300-Hz input tone |     | 11.1    |      |      |
| THD Total harmonic distortion                    | Internal 4.3-V equivalent reference <sup>(2)</sup> , 200 ksps, 9.6-kHz input tone                    |     | -65     |      | dB   |
|  | VDD5 as reference, 200 ksps, 9.6-kHz input tone  |     | -69     |      |      |
|  | Internal 1.44-V reference, voltage scaling disabled, 32 samples average, 200 ksps, 300-Hz input tone |     | -71     |      |      |
| SINAD, SNDR Signal-to-noise and Distortion ratio | Internal 4.3-V equivalent reference <sup>(2)</sup> , 200 ksps, 9.6-kHz input tone                    |     | 60      |      | dB   |
|  | VDD5 as reference, 200 ksps, 9.6-kHz input tone  |     | 63      |      |      |
|  | Internal 1.44-V reference, voltage scaling disabled, 32 samples average, 200 ksps, 300-Hz input tone |     | 69      |      |      |
| SFDR Spurious-free dynamic range                 | Internal 4.3-V equivalent reference <sup>(2)</sup> , 200 ksps, 9.6-kHz input tone                    |     | 67      |      | dB   |
|  | VDD5 as reference, 200 ksps, 9.6-kHz input tone  |     | 72      |      |      |
|  | Internal 1.44-V reference, voltage scaling disabled, 32 samples average, 200 ksps, 300-Hz input tone |     | 73      |      |      |

(1) Using IEEE Std 1241™-2010 for terminology and test methods.

(2) Input signal scaled down internally before conversion, as if voltage range was 0 to 4.3 V.

(3) No missing codes. Positive DNL typically varies from +0.3 to +3.5, depending on device (see [Figure 5-22](#)).

(4) For a typical example, see [Figure 5-23](#).

## ADC Characteristics (*continued*)

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{ V}$  and voltage scaling enabled, unless otherwise noted.<sup>(1)</sup>

| PARAMETER           | TEST CONDITIONS   | MIN | TYP                        | MAX | UNIT         |
|---------------------|---|-----|----------------------------|-----|--------------|
| Conversion time     | Serial conversion, time-to-output, 24-MHz clock   |     | 50                         |     | clock-cycles |
| Current consumption | Internal 4.3-V equivalent reference <sup>(2)</sup>  |     | 0.66                       |     | mA           |
| Current consumption | VDDS as reference   |     | 0.75                       |     | mA           |
| Reference voltage   | Equivalent fixed internal reference (input voltage scaling enabled). For best accuracy, the ADC conversion should be initiated through the TIRTOS API in order to include the gain/offset compensation factors stored in FCFG1.   |     | 4.3 <sup>(2)(5)</sup>      |     | V            |
| Reference voltage   | Fixed internal reference (input voltage scaling disabled). For best accuracy, the ADC conversion should be initiated through the TIRTOS API in order to include the gain/offset compensation factors stored in FCFG1. This value is derived from the scaled value (4.3V) as follows:<br>$V_{\text{ref}} = 4.3\text{V} \times 1408 / 4095$ |     | 1.48                       |     | V            |
| Reference voltage   | VDDS as reference (Also known as <i>RELATIVE</i> ) (input voltage scaling enabled)  |     | VDDS                       |     | V            |
| Reference voltage   | VDDS as reference (Also known as <i>RELATIVE</i> ) (input voltage scaling disabled)   |     | VDDS / 2.82 <sup>(5)</sup> |     | V            |
| Input Impedance     | 200 ksps, voltage scaling enabled. Capacitive input, Input impedance depends on sampling frequency and sampling time  |     | >1                         |     | MΩ           |

(5) Applied voltage must be within absolute maximum ratings ([Section 5.1](#)) at all times.

### 5.13 Temperature Sensor

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                                 | TEST CONDITIONS | MIN | TYP     | MAX | UNIT               |
|---|-----------------|-----|---------|-----|--------------------|
| Resolution                                |                 |     | 4       |     | $^\circ\text{C}$   |
| Range                                     |                 | –40 |         | 85  | $^\circ\text{C}$   |
| Accuracy                                  |                 |     | $\pm 5$ |     | $^\circ\text{C}$   |
| Supply voltage coefficient <sup>(1)</sup> |                 |     | 3.2     |     | $^\circ\text{C/V}$ |

(1) Automatically compensated when using supplied driver libraries.

### 5.14 Battery Monitor

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER  | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------|-----------------|-----|-----|-----|------|
| Resolution |                 |     | 50  |     | mV   |
| Range      |                 | 1.8 |     | 3.8 | V    |
| Accuracy   |                 |     | 13  |     | mV   |

### 5.15 Continuous Time Comparator

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                                       | TEST CONDITIONS           | MIN | TYP  | MAX  | UNIT          |
|---|---------------------------|-----|------|------|---------------|
| Input voltage range                             |                           | 0   |      | VDDS | V             |
| External reference voltage                      |                           | 0   |      | VDDS | V             |
| Internal reference voltage                      | DCOUPPL as reference      |     | 1.27 |      | V             |
| Offset  |                           |     | 3    |      | mV            |
| Hysteresis                                      |                           |     | <2   |      | mV            |
| Decision time                                   | Step from –10 mV to 10 mV |     | 0.72 |      | $\mu\text{s}$ |
| Current consumption when enabled <sup>(1)</sup> |                           |     | 8.6  |      | $\mu\text{A}$ |

(1) Additionally, the bias module must be enabled when running in standby mode.

## 5.16 Low-Power Clocked Comparator

$T_c = 25^\circ\text{C}$ ,  $V_{DDS} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                                 | TEST CONDITIONS           | MIN | TYP         | MAX       | UNIT        |
|---|---------------------------|-----|-------------|-----------|-------------|
| Input voltage range                       |                           | 0   |             | $V_{DDS}$ | V           |
| Clock frequency                           |                           |     | 32          |           | kHz         |
| Internal reference voltage, $V_{DDS} / 2$ |                           |     | 1.49 – 1.51 |           | V           |
| Internal reference voltage, $V_{DDS} / 3$ |                           |     | 1.01 – 1.03 |           | V           |
| Internal reference voltage, $V_{DDS} / 4$ |                           |     | 0.78 – 0.79 |           | V           |
| Internal reference voltage, $DCOUP_L / 1$ |                           |     | 1.25 – 1.28 |           | V           |
| Internal reference voltage, $DCOUP_L / 2$ |                           |     | 0.63 – 0.65 |           | V           |
| Internal reference voltage, $DCOUP_L / 3$ |                           |     | 0.42 – 0.44 |           | V           |
| Internal reference voltage, $DCOUP_L / 4$ |                           |     | 0.33 – 0.34 |           | V           |
| Offset                                    |                           |     | <2          |           | mV          |
| Hysteresis                                |                           |     | <5          |           | mV          |
| Decision time                             | Step from –50 mV to 50 mV |     | <1          |           | clock-cycle |
| Current consumption when enabled          |                           |     | 362         |           | nA          |

## 5.17 Programmable Current Source

$T_c = 25^\circ\text{C}$ ,  $V_{DDS} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                                | TEST CONDITIONS   | MIN | TYP       | MAX | UNIT          |
|--|---|-----|-----------|-----|---------------|
| Current source programmable output range |   |     | 0.25 – 20 |     | $\mu\text{A}$ |
| Resolution                               |   |     | 0.25      |     | $\mu\text{A}$ |
| Current consumption <sup>(1)</sup>       | Including current source at maximum programmable output |     | 23        |     | $\mu\text{A}$ |

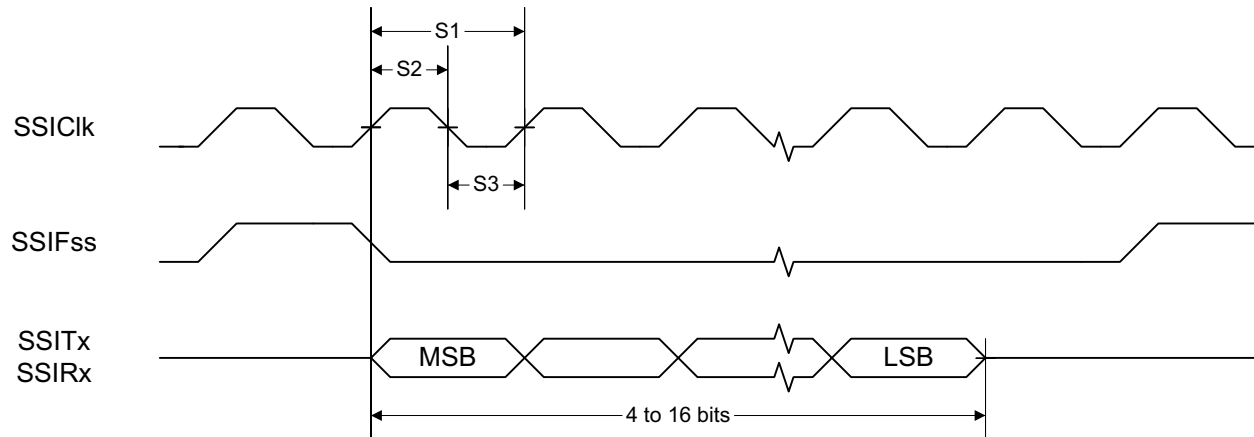
(1) Additionally, the bias module must be enabled when running in standby mode.

## 5.18 Synchronous Serial Interface (SSI)

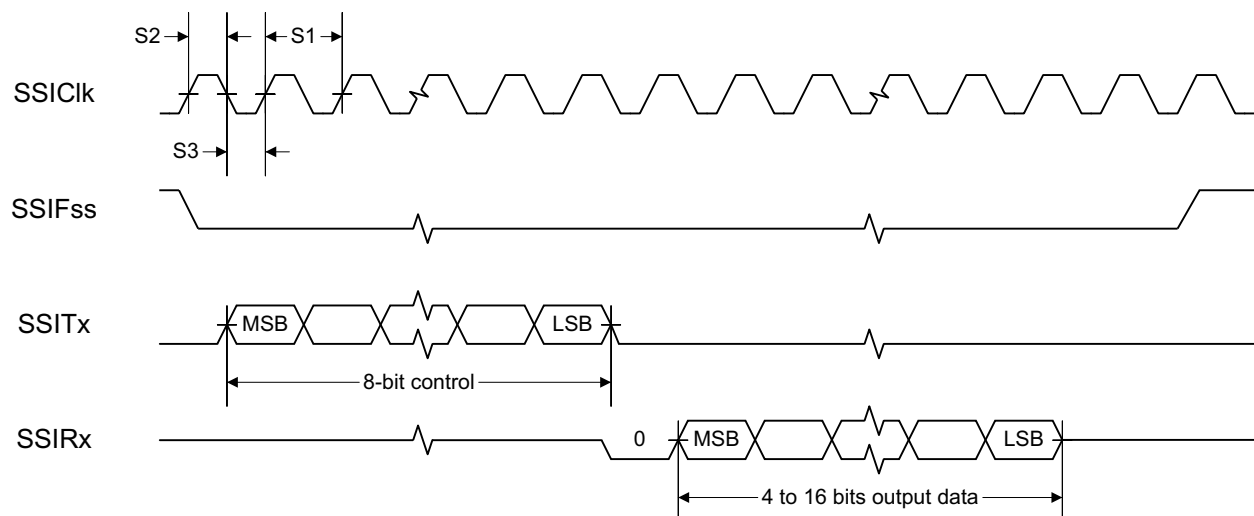
$T_c = 25^\circ\text{C}$ ,  $V_{DDS} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER  | TEST CONDITIONS   | MIN | TYP | MAX   | UNIT           |
|--|---|-----|-----|-------|----------------|
| $S1^{(1)} t_{clk\_per}$ (SSIClk period)                        | Device operating as SLAVE                                   | 12  |     | 65024 | system clocks  |
| $S2^{(1)} t_{clk\_high}$ (SSIClk high time)                    | Device operating as SLAVE                                   |     | 0.5 |       | $t_{clk\_per}$ |
| $S3^{(1)} t_{clk\_low}$ (SSIClk low time)                      | Device operating as SLAVE                                   |     | 0.5 |       | $t_{clk\_per}$ |
| $S1$ (TX only) <sup>(1)</sup> $t_{clk\_per}$ (SSIClk period)   | One-way communication to SLAVE - Device operating as MASTER | 4   |     | 65024 | system clocks  |
| $S1$ (TX and RX) <sup>(1)</sup> $t_{clk\_per}$ (SSIClk period) | Normal duplex operation - Device operating as MASTER        | 8   |     | 65024 | system clocks  |
| $S2^{(1)} t_{clk\_high}$ (SSIClk high time)                    | Device operating as MASTER                                  |     | 0.5 |       | $t_{clk\_per}$ |
| $S3^{(1)} t_{clk\_low}$ (SSIClk low time)                      | Device operating as MASTER                                  |     | 0.5 |       | $t_{clk\_per}$ |

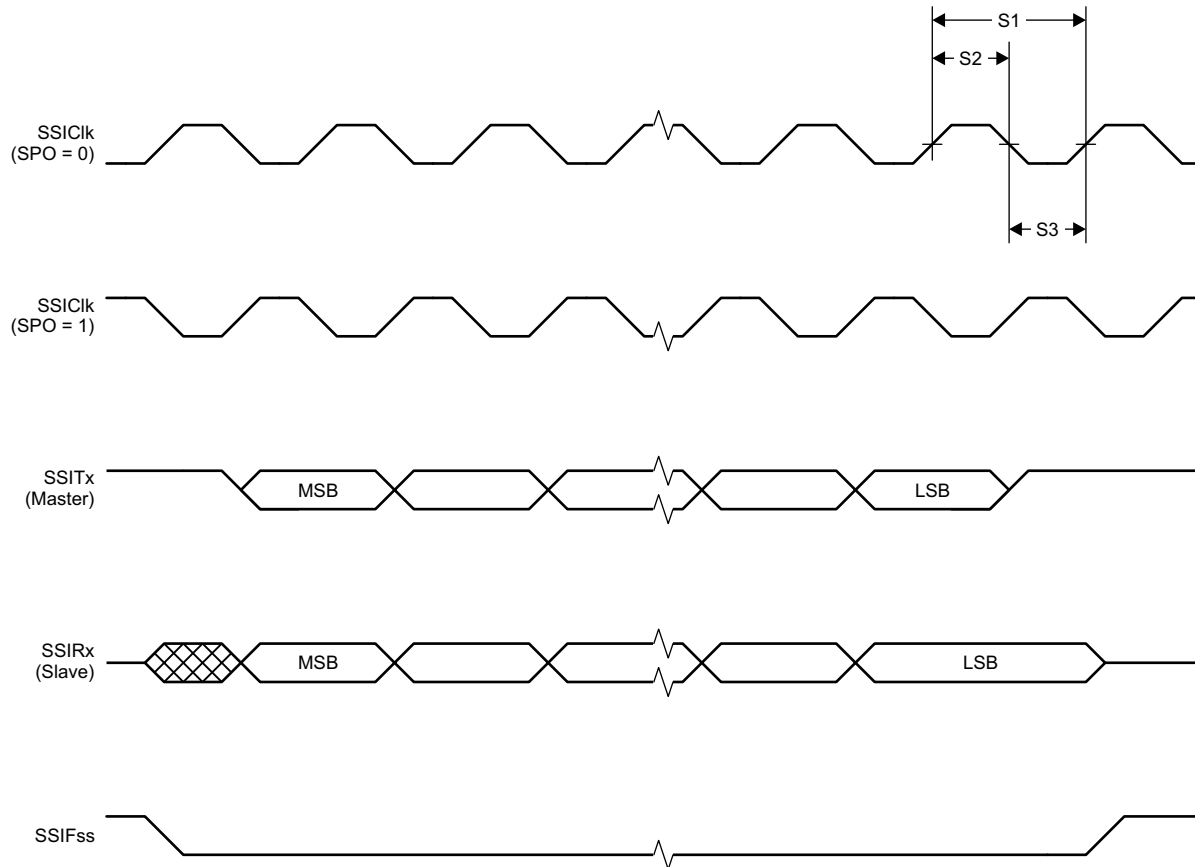
(1) Refer to SSI timing diagrams [Figure 5-1](#), [Figure 5-2](#), and [Figure 5-3](#).



**Figure 5-1. SSI Timing for TI Frame Format (FRF = 01), Single Transfer Timing Measurement**



**Figure 5-2. SSI Timing for MICROWIRE Frame Format (FRF = 10), Single Transfer**



**Figure 5-3. SSI Timing for SPI Frame Format (FRF = 00), With SPH = 1**

## 5.19 DC Characteristics

| PARAMETER   | TEST CONDITIONS   | MIN  | TYP  | MAX  | UNIT          |
|---|---|------|------|------|---------------|
| <b><math>T_A = 25^\circ\text{C}</math>, <math>V_{DDS} = 1.8\text{ V}</math></b> |   |      |      |      |               |
| GPIO VOH at 8-mA load   | IOCURR = 2, high-drive GPIOs only   | 1.32 | 1.54 |      | V             |
| GPIO VOL at 8-mA load   | IOCURR = 2, high-drive GPIOs only   |      | 0.26 | 0.32 | V             |
| GPIO VOH at 4-mA load   | IOCURR = 1  | 1.32 | 1.58 |      | V             |
| GPIO VOL at 4-mA load   | IOCURR = 1  |      | 0.21 | 0.32 | V             |
| GPIO pullup current   | Input mode, pullup enabled, $V_{pad} = 0\text{ V}$                        |      | 71.7 |      | $\mu\text{A}$ |
| GPIO pulldown current   | Input mode, pulldown enabled, $V_{pad} = V_{DDS}$                         |      | 21.1 |      | $\mu\text{A}$ |
| GPIO high/low input transition, no hysteresis                                   | IH = 0, transition between reading 0 and reading 1                        |      | 0.88 |      | V             |
| GPIO low-to-high input transition, with hysteresis                              | IH = 1, transition voltage for input read as 0 $\rightarrow$ 1            |      | 1.07 |      | V             |
| GPIO high-to-low input transition, with hysteresis                              | IH = 1, transition voltage for input read as 1 $\rightarrow$ 0            |      | 0.74 |      | V             |
| GPIO input hysteresis   | IH = 1, difference between 0 $\rightarrow$ 1 and 1 $\rightarrow$ 0 points |      | 0.33 |      | V             |

## DC Characteristics (continued)

| PARAMETER  | TEST CONDITIONS   | MIN | TYP  | MAX | UNIT                            |
|--|---|-----|------|-----|---------------------------------|
| <b>T<sub>A</sub> = 25°C, V<sub>DD5</sub> = 3.0 V</b> |   |     |      |     |                                 |
| GPIO VOH at 8-mA load                                | IOCURR = 2, high-drive GPIOs only                                 |     | 2.68 |     | V                               |
| GPIO VOL at 8-mA load                                | IOCURR = 2, high-drive GPIOs only                                 |     | 0.33 |     | V                               |
| GPIO VOH at 4-mA load                                | IOCURR = 1  |     | 2.72 |     | V                               |
| GPIO VOL at 4-mA load                                | IOCURR = 1  |     | 0.28 |     | V                               |
| <b>T<sub>A</sub> = 25°C, V<sub>DD5</sub> = 3.8 V</b> |   |     |      |     |                                 |
| GPIO pullup current                                  | Input mode, pullup enabled, V <sub>pad</sub> = 0 V                |     | 277  |     | μA                              |
| GPIO pulldown current                                | Input mode, pulldown enabled, V <sub>pad</sub> = V <sub>DD5</sub> |     | 113  |     | μA                              |
| GPIO high/low input transition, no hysteresis        | IH = 0, transition between reading 0 and reading 1                |     | 1.67 |     | V                               |
| GPIO low-to-high input transition, with hysteresis   | IH = 1, transition voltage for input read as 0 → 1                |     | 1.94 |     | V                               |
| GPIO high-to-low input transition, with hysteresis   | IH = 1, transition voltage for input read as 1 → 0                |     | 1.54 |     | V                               |
| GPIO input hysteresis                                | IH = 1, difference between 0 → 1 and 1 → 0 points                 |     | 0.4  |     | V                               |
| <b>T<sub>A</sub> = 25°C</b>                          |   |     |      |     |                                 |
| VIH  | Lowest GPIO input voltage reliably interpreted as a «High»        |     |      | 0.8 | V <sub>DD5</sub> <sup>(1)</sup> |
| VIL  | Highest GPIO input voltage reliably interpreted as a «Low»        | 0.2 |      |     | V <sub>DD5</sub> <sup>(1)</sup> |

(1) Each GPIO is referenced to a specific V<sub>DD5</sub> pin. See the technical reference manual listed in [Section 8.3](#) for more details.

## 5.20 Thermal Resistance Characteristics

| NAME                  | DESCRIPTION                                  | RSM (°C/W) <sup>(1) (2)</sup> | RHB (°C/W) <sup>(1) (2)</sup> | RGZ (°C/W) <sup>(1) (2)</sup> |
|-----------------------|--|-------------------------------|-------------------------------|-------------------------------|
| R <sub>θJA</sub>      | Junction-to-ambient thermal resistance       | 36.9                          | 32.8                          | 29.6                          |
| R <sub>θJC(top)</sub> | Junction-to-case (top) thermal resistance    | 30.3                          | 24.0                          | 15.7                          |
| R <sub>θJB</sub>      | Junction-to-board thermal resistance         | 7.6                           | 6.8                           | 6.2                           |
| Ψ <sub>jt</sub>       | Junction-to-top characterization parameter   | 0.4                           | 0.3                           | 0.3                           |
| Ψ <sub>jB</sub>       | Junction-to-board characterization parameter | 7.4                           | 6.8                           | 6.2                           |
| R <sub>θJC(bot)</sub> | Junction-to-case (bottom) thermal resistance | 2.1                           | 1.9                           | 1.9                           |

(1) °C/W = degrees Celsius per watt.

(2) These values are based on a JEDEC-defined 2S2P system (with the exception of the Theta JC [R<sub>θJC</sub>] value, which is based on a JEDEC-defined 1S0P system) and will change based on environment as well as application. For more information, see these EIA/JEDEC standards:

- JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions - Natural Convection (Still Air)*.
- JESD51-3, *Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages*.
- JESD51-7, *High Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages*.
- JESD51-9, *Test Boards for Area Array Surface Mount Package Thermal Measurements*.

Power dissipation of 2 W and an ambient temperature of 70°C is assumed.

## 5.21 Timing Requirements

|  |  | MIN | NOM | MAX | UNIT  |
|--|--|-----|-----|-----|-------|
| Rising supply-voltage slew rate  |  | 0   |     | 100 | mV/μs |
| Falling supply-voltage slew rate   |  | 0   |     | 20  | mV/μs |
| Falling supply-voltage slew rate, with low-power flash settings <sup>(1)</sup> |  |     |     | 3   | mV/μs |
| Positive temperature gradient in standby <sup>(2)</sup>                        | No limitation for negative temperature gradient, or outside standby mode |     |     | 5   | °C/s  |
| CONTROL INPUT AC CHARACTERISTICS <sup>(3)</sup>                                |  |     |     |     |       |
| RESET_N low duration   |  | 1   |     |     | μs    |

(1) For smaller coin cell batteries, with high worst-case end-of-life equivalent source resistance, a 22-μF VDD5 input capacitor (see [Figure 7-1](#)) must be used to ensure compliance with this slew rate.

(2) Applications using RCOSC\_LF as sleep timer must also consider the drift in frequency caused by a change in temperature (see [Section 5.11](#)).

(3)  $T_A = -40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ ,  $V_{DD5} = 1.7\text{ V}$  to  $3.8\text{ V}$ , unless otherwise noted.

## 5.22 Switching Characteristics

Measured on the TI CC2650EM-5XD reference design with  $T_c = 25^{\circ}\text{C}$ ,  $V_{DD5} = 3.0\text{ V}$ , unless otherwise noted.

| PARAMETER                | TEST CONDITIONS | MIN | TYP  | MAX | UNIT |
|--------------------------|-----------------|-----|------|-----|------|
| <b>WAKEUP AND TIMING</b> |                 |     |      |     |      |
| Idle → Active            |                 |     | 14   |     | μs   |
| Standby → Active         |                 |     | 151  |     | μs   |
| Shutdown → Active        |                 |     | 1015 |     | μs   |



## 5.23 Typical Characteristics

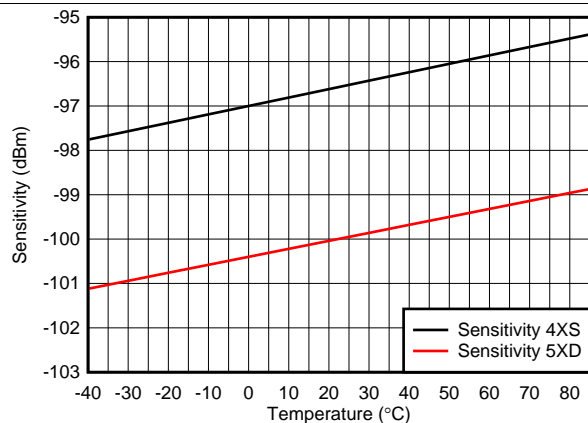


Figure 5-4. IEEE 802.15.4 Sensitivity vs Temperature

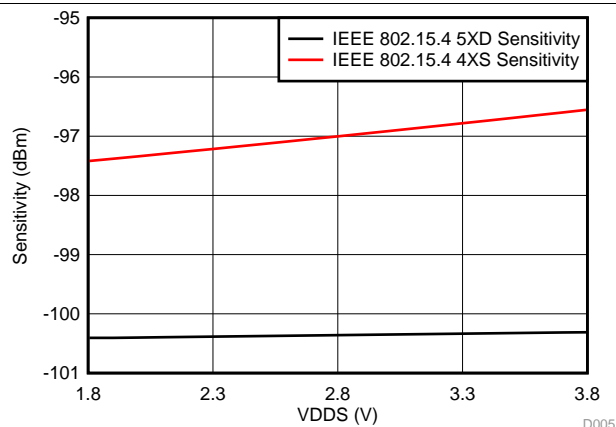


Figure 5-5. IEEE 802.15.4 Sensitivity vs Supply Voltage (VDD5)

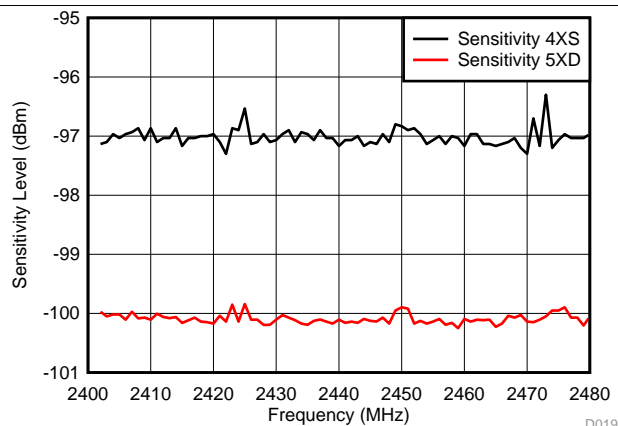


Figure 5-6. IEEE 802.15.4 Sensitivity vs Channel Frequency

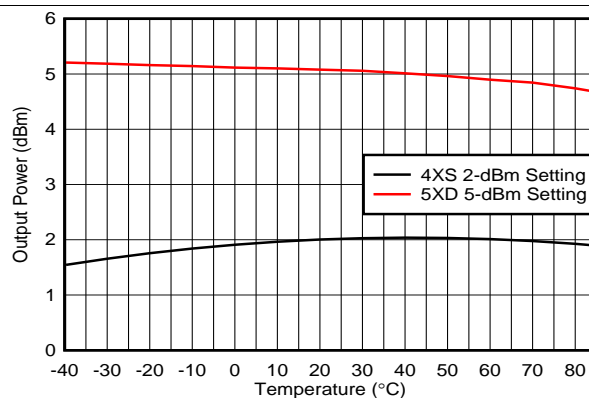


Figure 5-7. TX Output Power vs Temperature

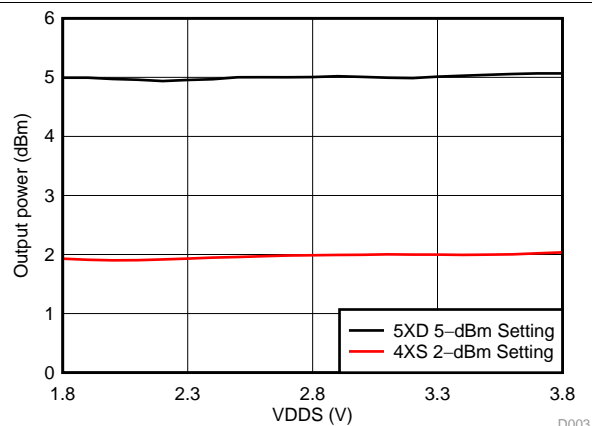


Figure 5-8. TX Output Power vs Supply Voltage (VDD5)

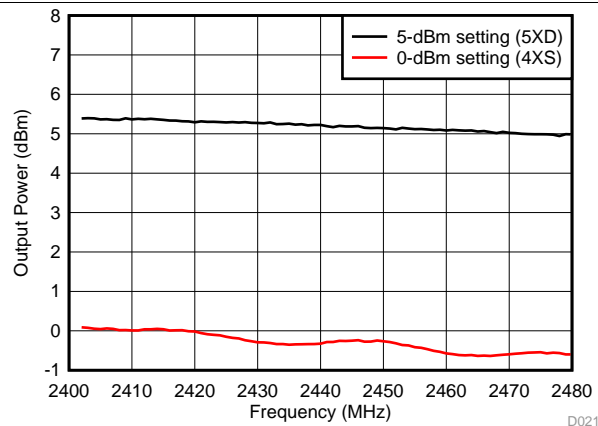


Figure 5-9. TX Output Power vs Channel Frequency

## Typical Characteristics (continued)

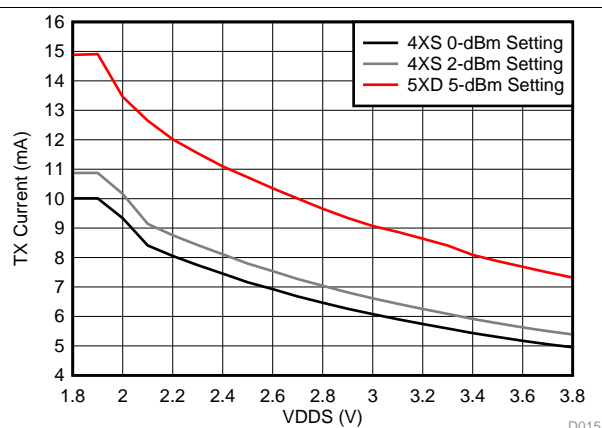


Figure 5-10. TX Current Consumption vs Supply Voltage (VDD5)

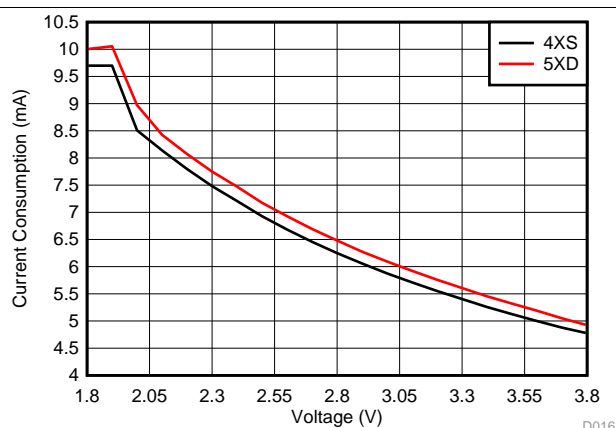


Figure 5-11. RX Mode Current vs Supply Voltage (VDD5)

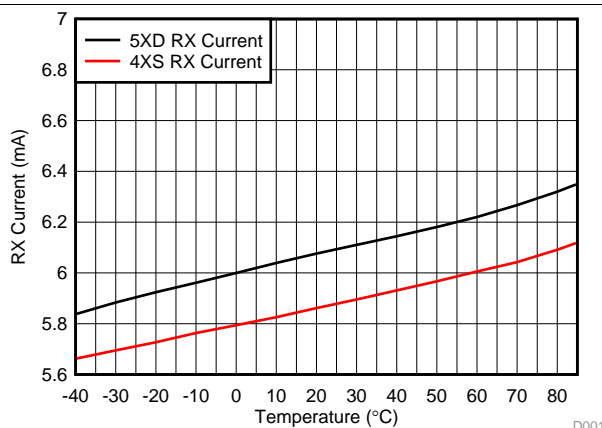


Figure 5-12. RX Mode Current Consumption vs Temperature

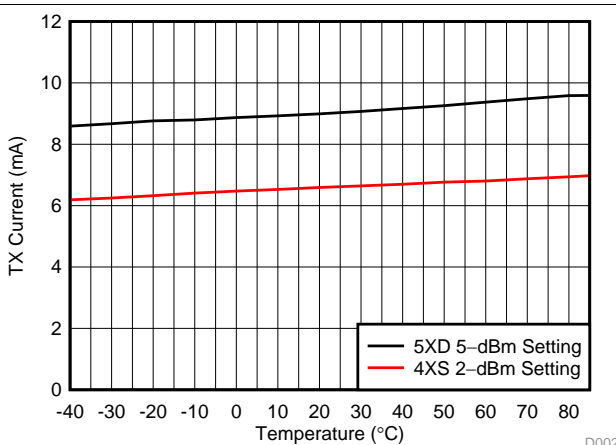


Figure 5-13. TX Mode Current Consumption vs Temperature

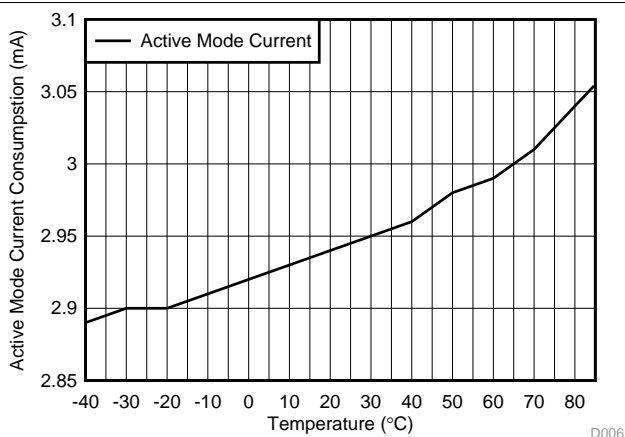


Figure 5-14. Active Mode (MCU Running, No Peripherals) Current Consumption vs Temperature

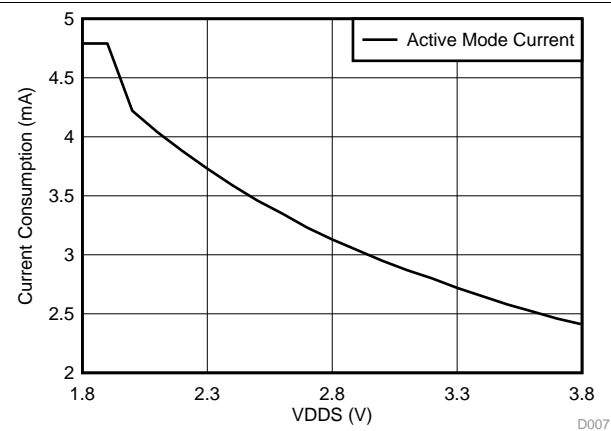
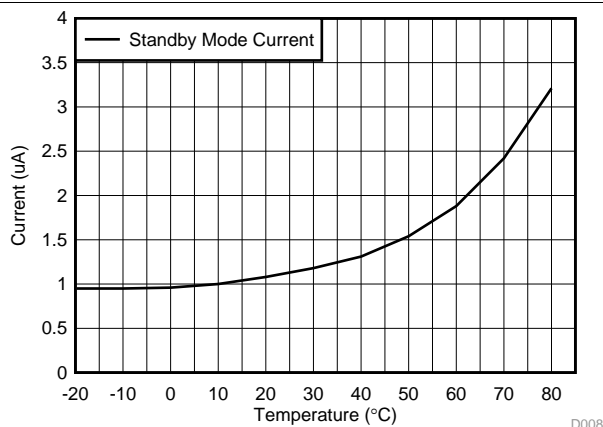
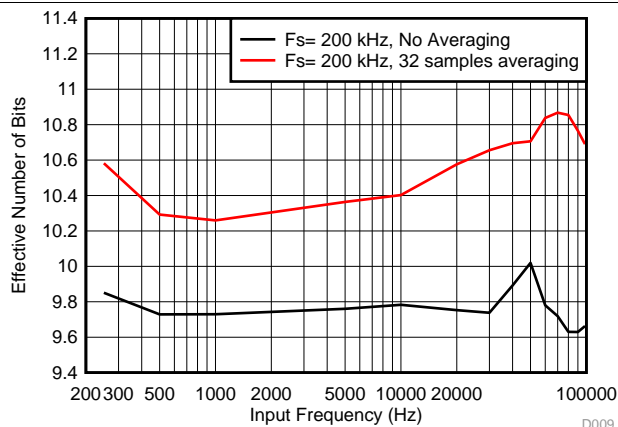


Figure 5-15. Active Mode (MCU Running, No Peripherals) Current Consumption vs Supply Voltage (VDD5)

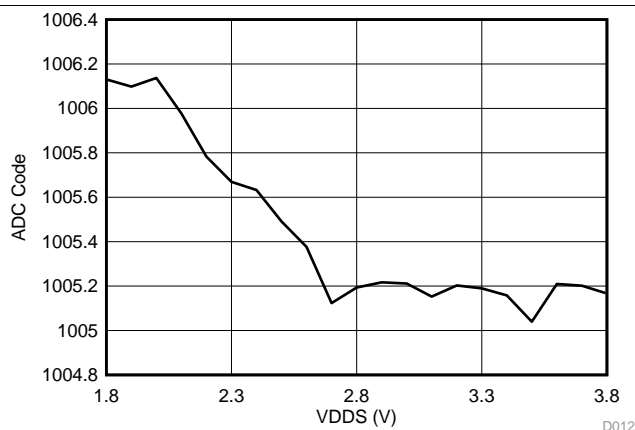
## Typical Characteristics (continued)



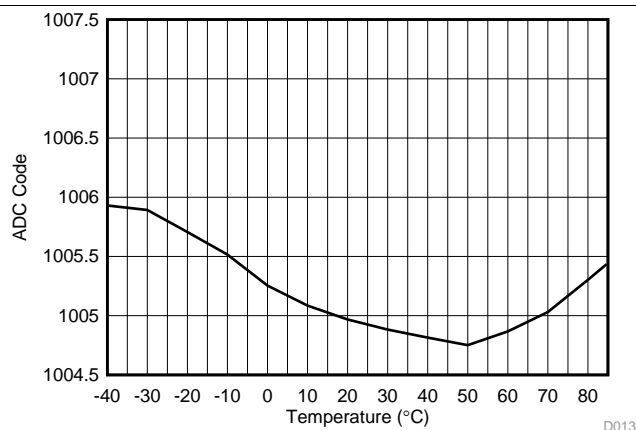
**Figure 5-16. Standby Mode Current Consumption With RCOSC RTC vs Temperature**



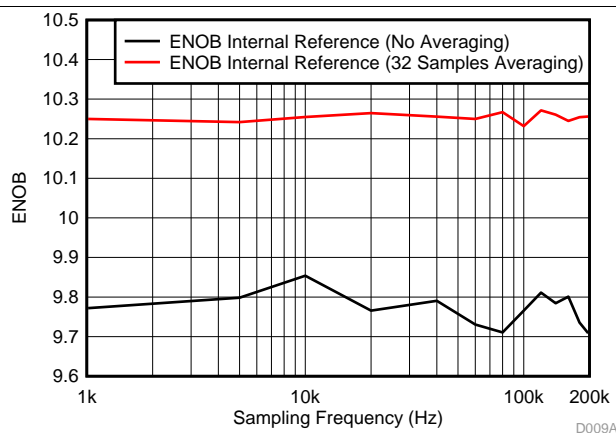
**Figure 5-17. SoC ADC Effective Number of Bits vs Input Frequency (Internal Reference, No Scaling)**



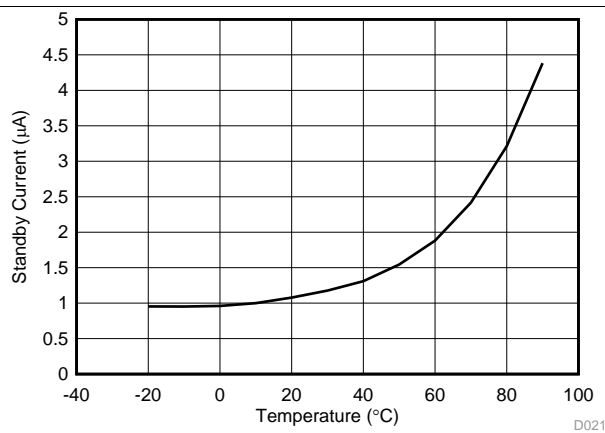
**Figure 5-18. SoC ADC Output vs Supply Voltage (Fixed Input, Internal Reference, No Scaling)**



**Figure 5-19. SoC ADC Output vs Temperature (Fixed Input, Internal Reference, No Scaling)**



**Figure 5-20. SoC ADC ENOB vs Sampling Frequency (Input Frequency = FS / 10)**



**Figure 5-21. Standby Mode Supply Current vs Temperature**

## Typical Characteristics *(continued)*

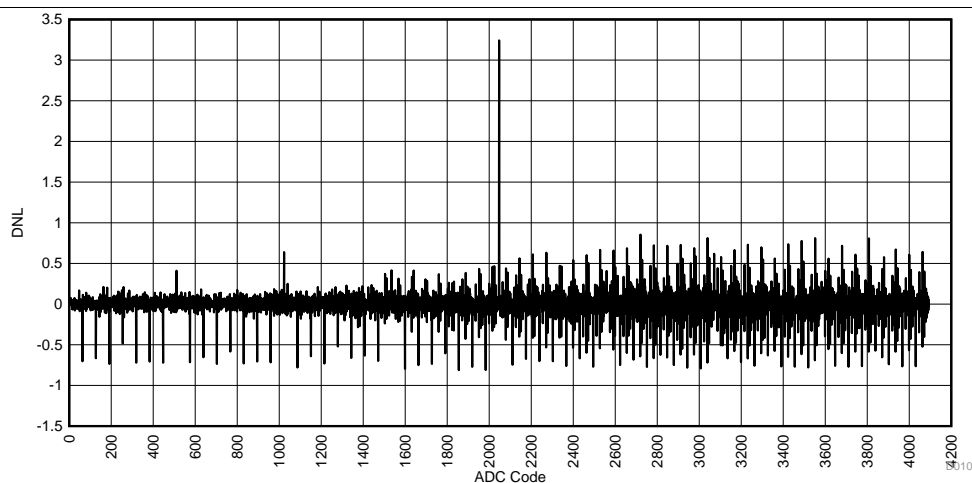


Figure 5-22. SoC ADC DNL vs ADC Code (Internal Reference, No Scaling)

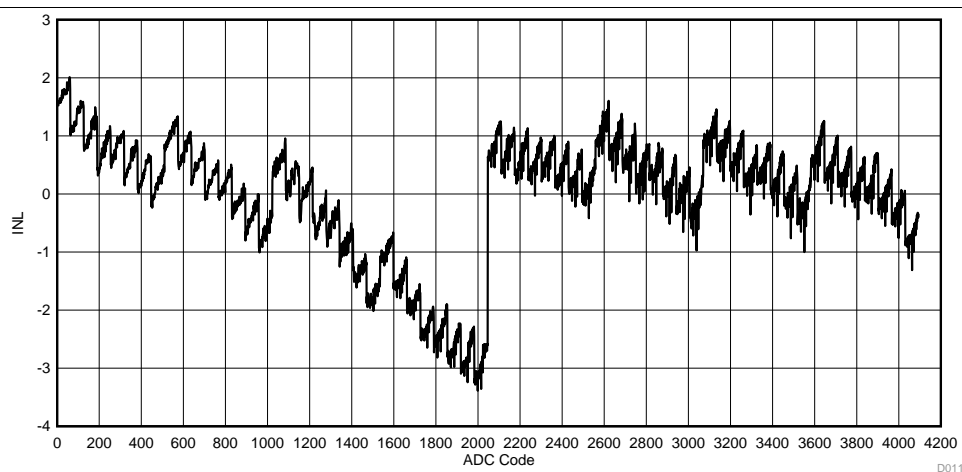


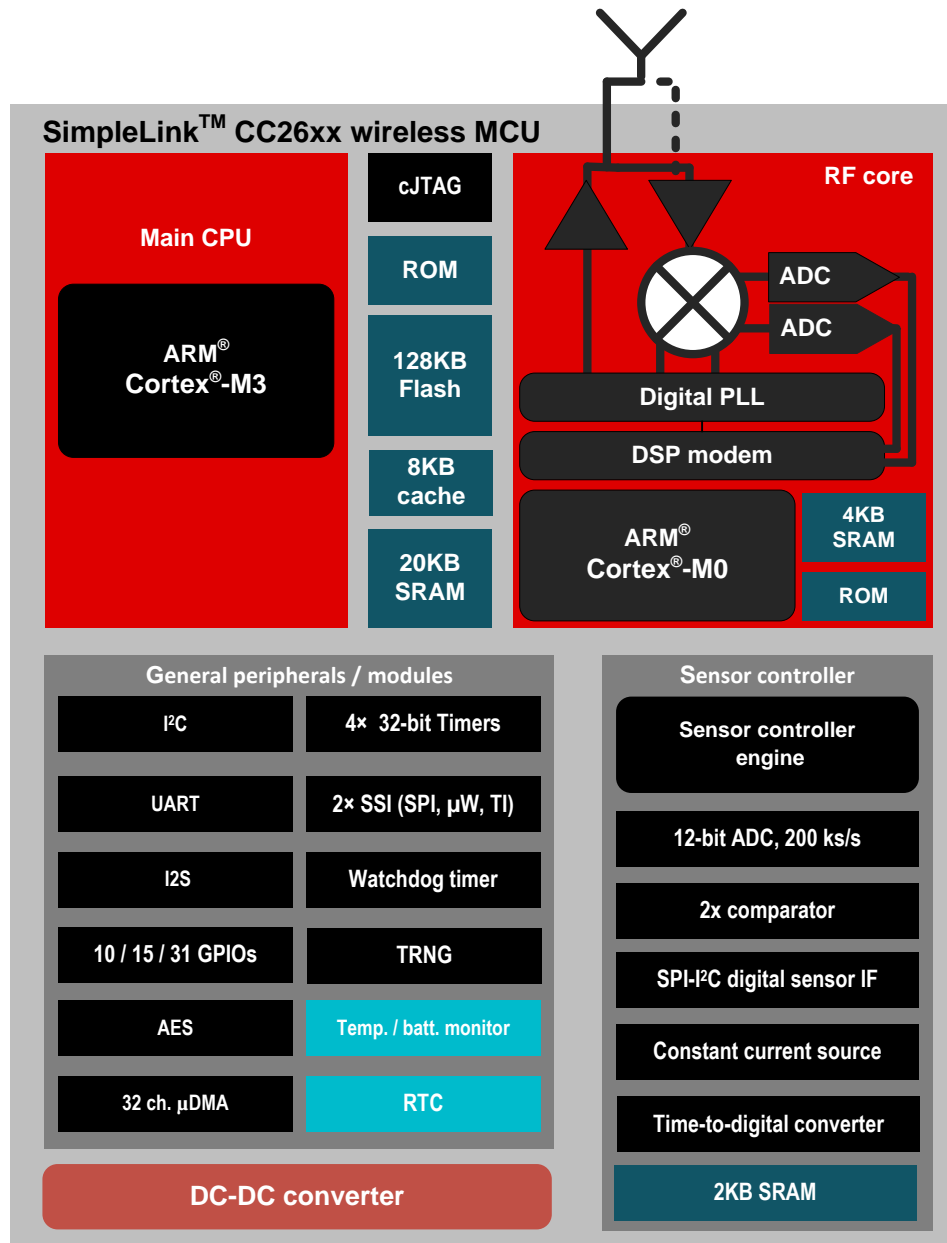
Figure 5-23. SoC ADC INL vs ADC Code (Internal Reference, No Scaling)

## 6 Detailed Description

### 6.1 Overview

The core modules of the CC26xx product family are shown in the [Section 6.2](#).

### 6.2 Functional Block Diagram



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## 6.3 Main CPU

The SimpleLink CC2630 Wireless MCU contains an ARM Cortex-M3 (CM3) 32-bit CPU, which runs the application and the higher layers of the protocol stack.

The CM3 processor provides a high-performance, low-cost platform that meets the system requirements of minimal memory implementation, and low-power consumption, while delivering outstanding computational performance and exceptional system response to interrupts.

CM3 features include the following:

- 32-bit ARM Cortex-M3 architecture optimized for small-footprint embedded applications
- Outstanding processing performance combined with fast interrupt handling
- ARM Thumb®-2 mixed 16- and 32-bit instruction set delivers the high performance expected of a 32-bit ARM core in a compact memory size usually associated with 8- and 16-bit devices, typically in the range of a few kilobytes of memory for microcontroller-class applications:
  - Single-cycle multiply instruction and hardware divide
  - Atomic bit manipulation (bit-banding), delivering maximum memory use and streamlined peripheral control
  - Unaligned data access, enabling data to be efficiently packed into memory
- Fast code execution permits slower processor clock or increases sleep mode time
- Harvard architecture characterized by separate buses for instruction and data
- Efficient processor core, system, and memories
- Hardware division and fast digital-signal-processing oriented multiply accumulate
- Saturating arithmetic for signal processing
- Deterministic, high-performance interrupt handling for time-critical applications
- Enhanced system debug with extensive breakpoint and trace capabilities
- Serial wire trace reduces the number of pins required for debugging and tracing
- Migration from the ARM7™ processor family for better performance and power efficiency
- Optimized for single-cycle flash memory use
- Ultralow-power consumption with integrated sleep modes
- 1.25 DMIPS per MHz

## 6.4 RF Core

The RF Core contains an ARM Cortex-M0 processor that interfaces the analog RF and base-band circuitries, handles data to and from the system side, and assembles the information bits in a given packet structure. The RF core offers a high level, command-based API to the main CPU.

The RF core is capable of autonomously handling the time-critical aspects of the radio protocols (802.15.4 ZigBee) thus offloading the main CPU and leaving more resources for the user application.

The RF core has a dedicated 4-KB SRAM block and runs initially from separate ROM memory. The ARM Cortex-M0 processor is not programmable by customers.

## 6.5 Sensor Controller

The Sensor Controller contains circuitry that can be selectively enabled in standby mode. The peripherals in this domain may be controlled by the Sensor Controller Engine which is a proprietary power-optimized CPU. This CPU can read and monitor sensors or perform other tasks autonomously, thereby significantly reducing power consumption and offloading the main CM3 CPU.

The Sensor Controller is set up using a PC-based configuration tool, called Sensor Controller Studio, and potential use cases may be (but are not limited to):

- Analog sensors using integrated ADC
- Digital sensors using GPIOs, bit-banged I<sup>2</sup>C, and SPI
- UART communication for sensor reading or debugging
- Capacitive sensing
- Waveform generation
- Pulse counting
- Keyboard scan
- Quadrature decoder for polling rotation sensors
- Oscillator calibration

---

### NOTE

Texas Instruments provides application examples for some of these use cases, but not for all of them.

---

The peripherals in the Sensor Controller include the following:

- The low-power clocked comparator can be used to wake the device from any state in which the comparator is active. A configurable internal reference can be used in conjunction with the comparator. The output of the comparator can also be used to trigger an interrupt or the ADC.
- Capacitive sensing functionality is implemented through the use of a constant current source, a time-to-digital converter, and a comparator. The continuous time comparator in this block can also be used as a higher-accuracy alternative to the low-power clocked comparator. The Sensor Controller will take care of baseline tracking, hysteresis, filtering and other related functions.
- The ADC is a 12-bit, 200-kSamples/s ADC with eight inputs and a built-in voltage reference. The ADC can be triggered by many different sources, including timers, I/O pins, software, the analog comparator, and the RTC.
- The Sensor Controller also includes a SPI–I<sup>2</sup>C digital interface.
- The analog modules can be connected to up to eight different GPIOs.

The peripherals in the Sensor Controller can also be controlled from the main application processor.

**Table 6-1. GPIOs Connected to the Sensor Controller<sup>(1)</sup>**

| ANALOG CAPABLE | 7 × 7 RGZ<br>DIO NUMBER | 5 × 5 RHB<br>DIO NUMBER | 4 × 4 RSM<br>DIO NUMBER |
|----------------|-------------------------|-------------------------|-------------------------|
| Y              | 30                      | 14                      |                         |
| Y              | 29                      | 13                      |                         |
| Y              | 28                      | 12                      |                         |
| Y              | 27                      | 11                      | 9                       |
| Y              | 26                      | 9                       | 8                       |
| Y              | 25                      | 10                      | 7                       |
| Y              | 24                      | 8                       | 6                       |
| Y              | 23                      | 7                       | 5                       |
| N              | 7                       | 4                       | 2                       |
| N              | 6                       | 3                       | 1                       |
| N              | 5                       | 2                       | 0                       |
| N              | 4                       | 1                       |                         |
| N              | 3                       | 0                       |                         |
| N              | 2                       |                         |                         |
| N              | 1                       |                         |                         |
| N              | 0                       |                         |                         |

(1) Depending on the package size, up to 16 pins can be connected to the Sensor Controller. Up to 8 of these pins can be connected to analog modules.

## 6.6 Memory

The flash memory provides nonvolatile storage for code and data. The flash memory is in-system programmable.

The SRAM (static RAM) can be used for both storage of data and execution of code and is split into two 4-KB blocks and two 6-KB blocks. Retention of the RAM contents in standby mode can be enabled or disabled individually for each block to minimize power consumption. In addition, if flash cache is disabled, the 8-KB cache can be used as a general-purpose RAM.

The ROM provides preprogrammed embedded TI RTOS kernel, Driverlib and lower layer protocol stack software (802.15.4 MAC). It also contains a bootloader that can be used to reprogram the device using SPI or UART.

## 6.7 Debug

The on-chip debug support is done through a dedicated cJTAG (IEEE 1149.7) or JTAG (IEEE 1149.1) interface.



## 6.8 Power Management

To minimize power consumption, the CC2630 device supports a number of power modes and power management features (see [Table 6-2](#)).

**Table 6-2. Power Modes**

| MODE                                      | SOFTWARE CONFIGURABLE POWER MODES |                     |                            |           | RESET PIN HELD |
|---|-----------------------------------|---------------------|----------------------------|-----------|----------------|
|   | ACTIVE                            | IDLE                | STANDBY                    | SHUTDOWN  |                |
| <b>CPU</b>                                | Active                            | Off                 | Off                        | Off       | Off            |
| <b>Flash</b>                              | On                                | Available           | Off                        | Off       | Off            |
| <b>SRAM</b>                               | On                                | On                  | On                         | Off       | Off            |
| <b>Radio</b>                              | Available                         | Available           | Off                        | Off       | Off            |
| <b>Supply System</b>                      | On                                | On                  | Duty Cycled                | Off       | Off            |
| Current                                   | 1.45 mA + 31 µA/MHz               | 550 µA              | 1 µA                       | 0.15 µA   | 0.1 µA         |
| Wake-up Time to CPU Active <sup>(1)</sup> | –                                 | 14 µs               | 151 µs                     | 1015 µs   | 1015 µs        |
| Register Retention                        | Full                              | Full                | Partial                    | No        | No             |
| SRAM Retention                            | Full                              | Full                | Full                       | No        | No             |
| High-Speed Clock                          | XOSC_HF or RCOSC_HF               | XOSC_HF or RCOSC_HF | Off                        | Off       | Off            |
| Low-Speed Clock                           | XOSC_LF or RCOSC_LF               | XOSC_LF or RCOSC_LF | XOSC_LF or RCOSC_LF        | Off       | Off            |
| Peripherals                               | Available                         | Available           | Off                        | Off       | Off            |
| Sensor Controller                         | Available                         | Available           | Available                  | Off       | Off            |
| Wake up on RTC                            | Available                         | Available           | Available                  | Off       | Off            |
| Wake up on Pin Edge                       | Available                         | Available           | Available                  | Available | Off            |
| Wake up on Reset Pin                      | Available                         | Available           | Available                  | Available | Available      |
| Brown Out Detector (BOD)                  | Active                            | Active              | Duty Cycled <sup>(2)</sup> | Off       | N/A            |
| Power On Reset (POR)                      | Active                            | Active              | Active                     | Active    | N/A            |

(1) Not including RTOS overhead

(2) The Brown Out Detector is disabled between recharge periods in STANDBY. Lowering the supply voltage below the BOD threshold between two recharge periods while in STANDBY may cause the BOD to lock the device upon wake-up until a Reset/POR releases it. To avoid this, it is recommended that STANDBY mode is avoided if there is a risk that the supply voltage (VDD5) may drop below the specified operating voltage range. For the same reason, it is also good practice to ensure that a power cycling operation, such as a battery replacement, triggers a Power-on-reset by ensuring that the VDD5 decoupling network is fully depleted before applying supply voltage again (for example, inserting new batteries).

In active mode, the application CM3 CPU is actively executing code. Active mode provides normal operation of the processor and all of the peripherals that are currently enabled. The system clock can be any available clock source (see [Table 6-2](#)).

In idle mode, all active peripherals can be clocked, but the Application CPU core and memory are not clocked and no code is executed. Any interrupt event will bring the processor back into active mode.

In standby mode, only the always-on domain (AON) is active. An external wake event, RTC event, or sensor-controller event is required to bring the device back to active mode. MCU peripherals with retention do not need to be reconfigured when waking up again, and the CPU continues execution from where it went into standby mode. All GPIOs are latched in standby mode.

In shutdown mode, the device is turned off entirely, including the AON domain and the Sensor Controller. The I/Os are latched with the value they had before entering shutdown mode. A change of state on any I/O pin defined as a *wake from Shutdown pin* wakes up the device and functions as a reset trigger. The CPU can differentiate between a reset in this way, a reset-by-reset pin, or a power-on-reset by reading the reset status register. The only state retained in this mode is the latched I/O state and the Flash memory contents.

The Sensor Controller is an autonomous processor that can control the peripherals in the Sensor Controller independently of the main CPU, which means that the main CPU does not have to wake up, for example, to execute an ADC sample or poll a digital sensor over SPI. The main CPU saves both current and wake-up time that would otherwise be wasted. The Sensor Controller Studio enables the user to configure the sensor controller and choose which peripherals are controlled and which conditions wake up the main CPU.

## 6.9 Clock Systems

The CC2630 supports two external and two internal clock sources.

A 24-MHz crystal is required as the frequency reference for the radio. This signal is doubled internally to create a 48-MHz clock.

The 32-kHz crystal is optional. The low-speed crystal oscillator is designed for use with a 32-kHz watch-type crystal.

The internal high-speed oscillator (48-MHz) can be used as a clock source for the CPU subsystem.

The internal low-speed oscillator (32.768-kHz) can be used as a reference if the low-power crystal oscillator is not used.

The 32-kHz clock source can be used as external clocking reference through GPIO.

## 6.10 General Peripherals and Modules

The I/O controller controls the digital I/O pins and contains multiplexer circuitry to allow a set of peripherals to be assigned to I/O pins in a flexible manner. All digital I/Os are interrupt and wake-up capable, have a programmable pullup and pulldown function and can generate an interrupt on a negative or positive edge (configurable). When configured as an output, pins can function as either push-pull or open-drain. Five GPIOs have high drive capabilities (marked in **bold** in [Section 4](#)).

The SSIs are synchronous serial interfaces that are compatible with SPI, MICROWIRE, and Texas Instruments synchronous serial interfaces. The SSIs support both SPI master and slave up to 4 MHz.

The UART implements a universal asynchronous receiver/transmitter function. It supports flexible baud-rate generation up to a maximum of 3 Mbps.

Timer 0 is a general-purpose timer module (GPTM), which provides two 16-bit timers. The GPTM can be configured to operate as a single 32-bit timer, dual 16-bit timers or as a PWM module.

Timer 1, Timer 2, and Timer 3 are also GPTMs. Each of these timers is functionally equivalent to Timer 0.

In addition to these four timers, the RF core has its own timer to handle timing for RF protocols; the RF timer can be synchronized to the RTC.

The I<sup>2</sup>C interface is used to communicate with devices compatible with the I<sup>2</sup>C standard. The I<sup>2</sup>C interface is capable of 100-kHz and 400-kHz operation, and can serve as both I<sup>2</sup>C master and I<sup>2</sup>C slave.

The TRNG module provides a true, nondeterministic noise source for the purpose of generating keys, initialization vectors (IVs), and other random number requirements. The TRNG is built on 24 ring oscillators that create unpredictable output to feed a complex nonlinear combinatorial circuit.

The watchdog timer is used to regain control if the system fails due to a software error after an external device fails to respond as expected. The watchdog timer can generate an interrupt or a reset when a predefined time-out value is reached.

The device includes a direct memory access ( $\mu$ DMA) controller. The  $\mu$ DMA controller provides a way to offload data transfer tasks from the CM3 CPU, allowing for more efficient use of the processor and the available bus bandwidth. The  $\mu$ DMA controller can perform transfer between memory and peripherals. The  $\mu$ DMA controller has dedicated channels for each supported on-chip module and can be programmed to automatically perform transfers between peripherals and memory as the peripheral is ready to transfer more data. Some features of the  $\mu$ DMA controller include the following (this is not an exhaustive list):

- Highly flexible and configurable channel operation of up to 32 channels
- Transfer modes:
  - Memory-to-memory
  - Memory-to-peripheral
  - Peripheral-to-memory
  - Peripheral-to-peripheral
- Data sizes of 8, 16, and 32 bits

The AON domain contains circuitry that is always enabled, except for in Shutdown (where the digital supply is off). This circuitry includes the following:

- The RTC can be used to wake the device from any state where it is active. The RTC contains three compare and one capture registers. With software support, the RTC can be used for clock and calendar operation. The RTC is clocked from the 32-kHz RC oscillator or crystal. The RTC can also be compensated to tick at the correct frequency even when the internal 32-kHz RC oscillator is used instead of a crystal.
- The battery monitor and temperature sensor are accessible by software and give a battery status indication as well as a coarse temperature measure.

## 6.11 Voltage Supply Domains

The CC2630 device can interface to two or three different voltage domains depending on the package type. On-chip level converters ensure correct operation as long as the signal voltage on each input/output pin is set with respect to the corresponding supply pin (VDDS, VDDS2 or VDDS3). lists the pin-to-VDDS mapping.

**Table 6-3. Pin function to VDDS mapping table**

|                     | Package              |                     |                    |
|---------------------|----------------------|---------------------|--------------------|
|                     | VQFN 7 × 7 (RGZ)     | VQFN 5 × 5 (RHB)    | VQFN 4 × 4 (RSM)   |
| VDDS <sup>(1)</sup> | DIO 23–30<br>Reset_N | DIO 7–14<br>Reset_N | DIO 5–9<br>Reset_N |
| VDDS2               | DIO 0–11             | DIO 0–6<br>JTAG     | DIO 0–4<br>JTAG    |
| VDDS3               | DIO 12–22<br>JTAG    | N/A                 | N/A                |

(1) VDDS\_DCDC must be connected to VDDS on the PCB

## 6.12 System Architecture

Depending on the product configuration, CC26xx can function either as a Wireless Network Processor (WNP—an IC running the wireless protocol stack, with the application running on a separate MCU), or as a System-on-Chip (SoC), with the application and protocol stack running on the ARM CM3 core inside the device.

In the first case, the external host MCU communicates with the device using SPI or UART. In the second case, the application must be written according to the application framework supplied with the wireless protocol stack.

## 7 Application, Implementation, and Layout

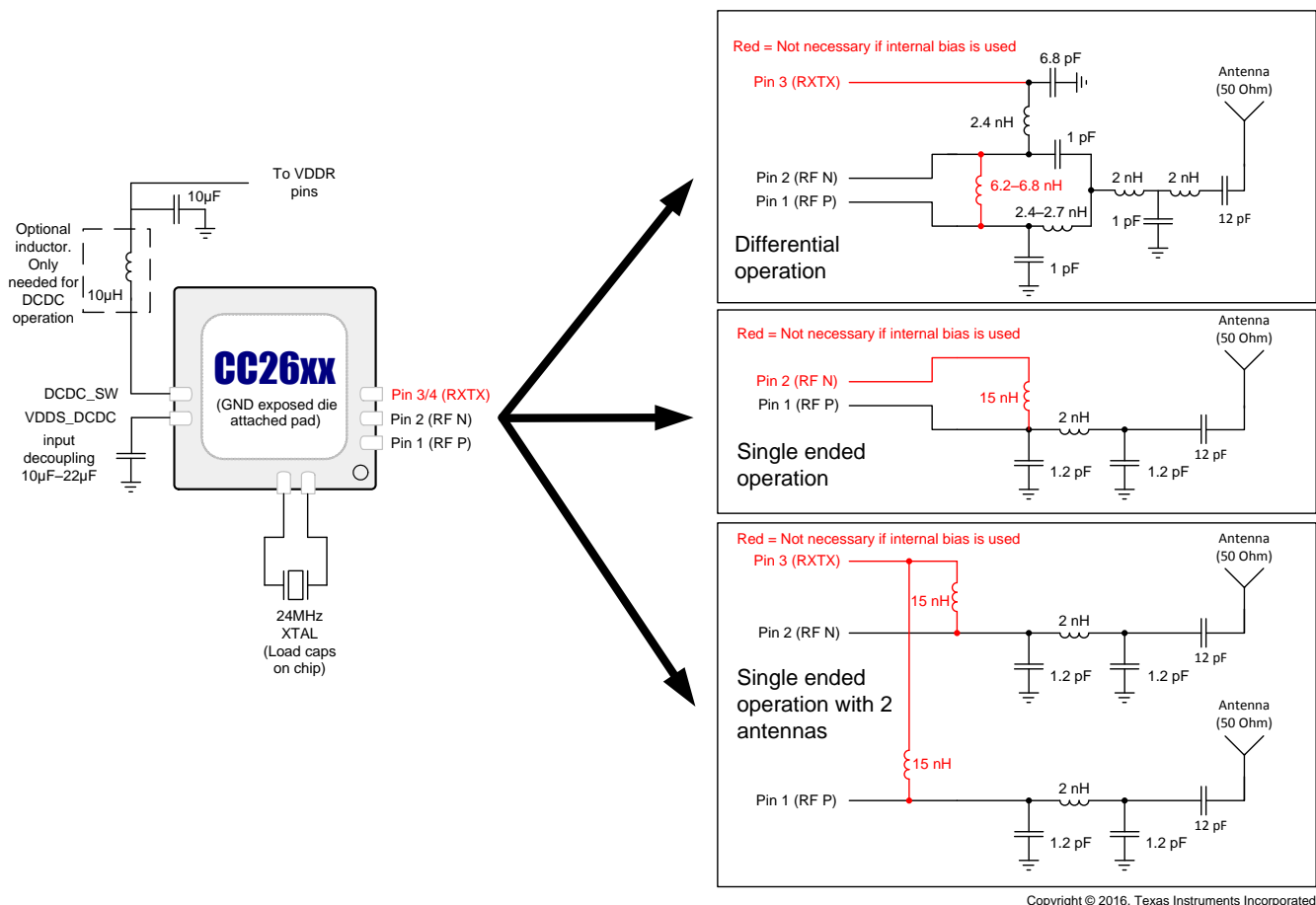
### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 7.1 Application Information

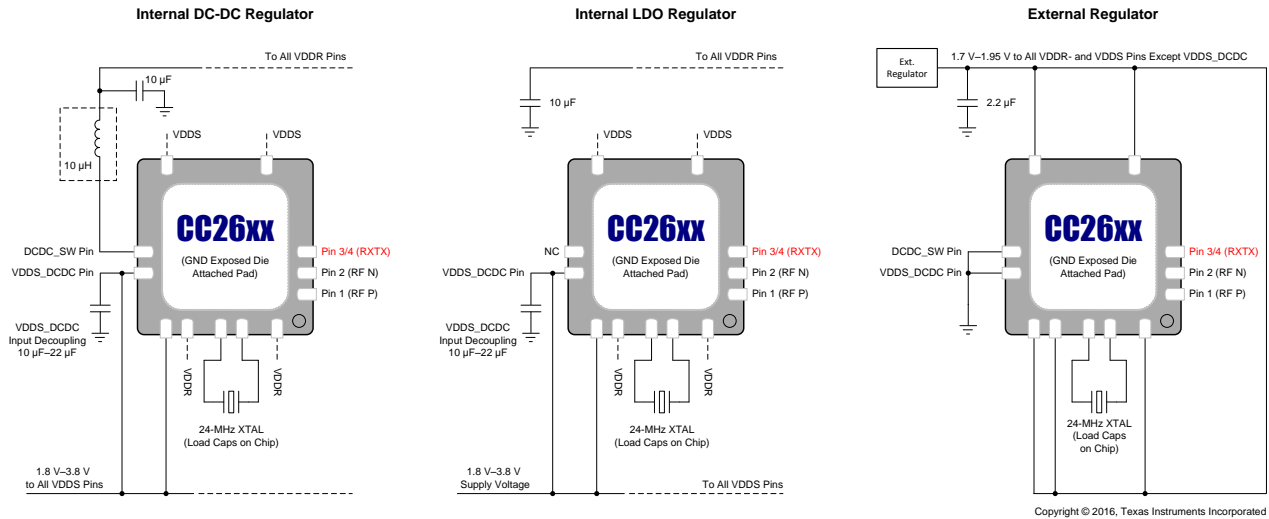
Very few external components are required for the operation of the CC2630 device. This section provides some general information about the various configuration options when using the CC2630 in an application, and then shows two examples of application circuits with schematics and layout. This is only a small selection of the many application circuit examples available as complete reference designs from the product folder on [www.ti.com](http://www.ti.com).

Figure 7-1 shows the various RF front-end configuration options. The RF front end can be used in differential- or single-ended configurations with the options of having internal or external biasing. These options allow for various trade-offs between cost, board space, and RF performance. Differential operation with external bias gives the best performance while single-ended operation with internal bias gives the least amount of external components and the lowest power consumption. Reference designs exist for each of these options.



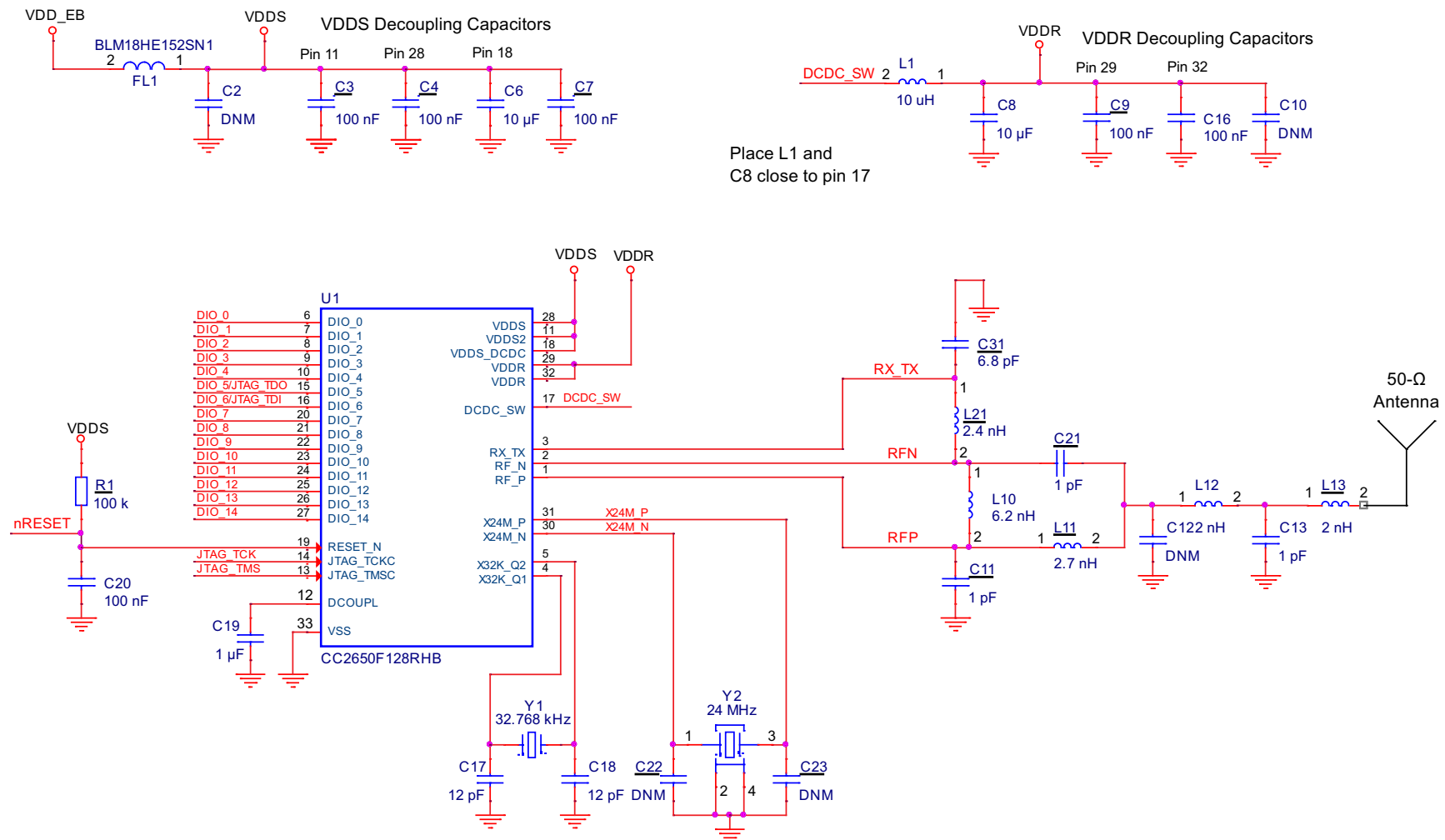
**Figure 7-1. CC2630 Application Circuit**

Figure 7-2 shows the various supply voltage configuration options. Not all power supply decoupling capacitors or digital I/Os are shown. Exact pin positions will vary between the different package options. For a detailed overview of power supply decoupling and wiring, see the TI reference designs and the CC26xx technical reference manual (Section 8.3).



### Figure 7-2. Supply Voltage Configurations

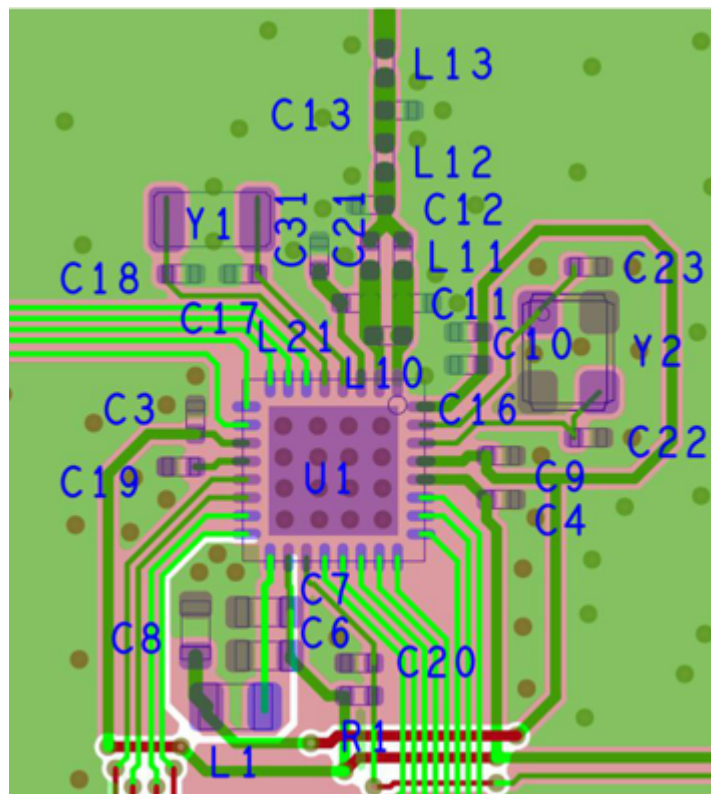
## 7.2 5 × 5 External Differential (5XD) Application Circuit



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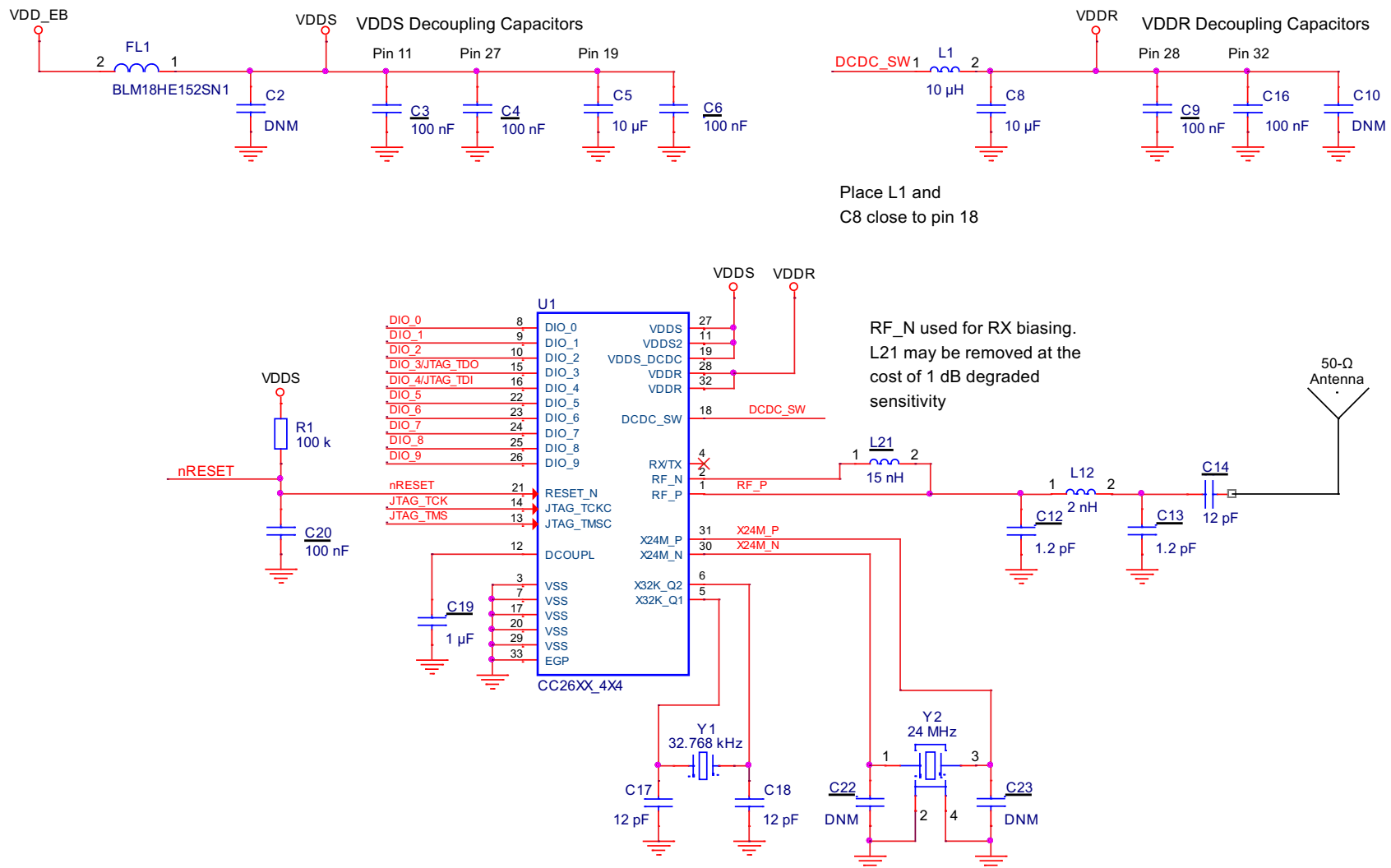
**Figure 7-3. 5 × 5 External Differential (5XD) Application Circuit**

## 7.2.1 Layout



**Figure 7-4. 5 × 5 External Differential (5XD) Layout**

### 7.3 4 × 4 External Single-ended (4XS) Application Circuit



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### Figure 7-5. 4 x 4 External Single-ended (4XS) Application Circuit



### 7.3.1 Layout

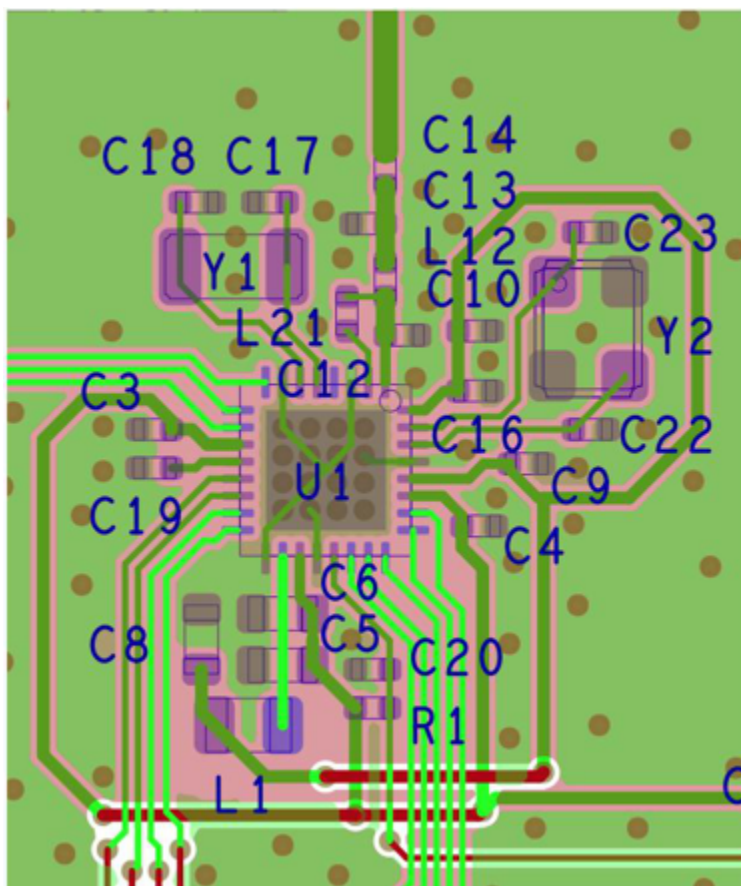


Figure 7-6. 4 × 4 External Single-ended (4XS) Layout

## 8 Device and Documentation Support

### 8.1 Device Nomenclature

To designate the stages in the product development cycle, TI assigns prefixes to all part numbers and date-code. Each device has one of three prefixes/identifications: X, P, or null (no prefix) (for example, CC2630 is in production; therefore, no prefix/identification is assigned).

Device development evolutionary flow:

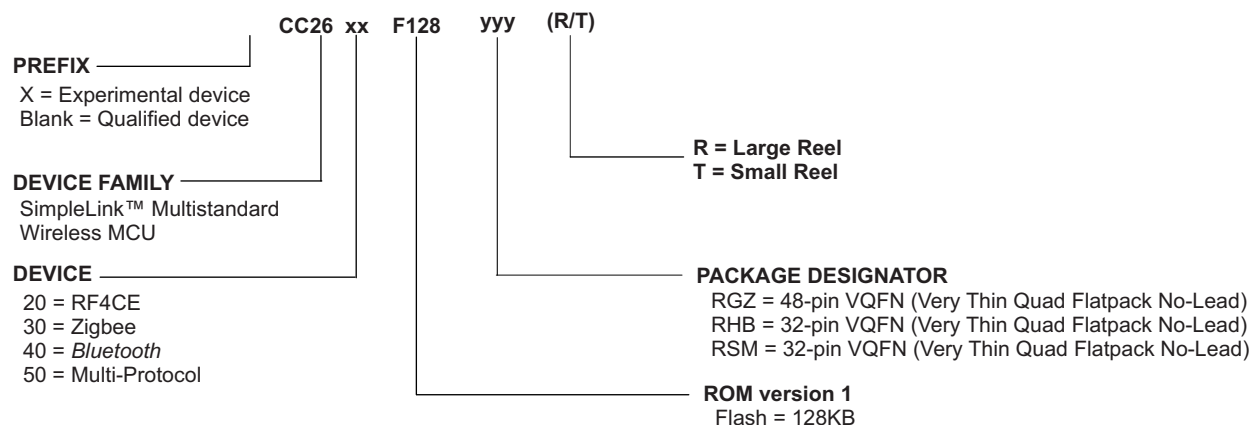
- X** Experimental device that is not necessarily representative of the final device's electrical specifications and may not use production assembly flow.
- P** Prototype device that is not necessarily the final silicon die and may not necessarily meet final electrical specifications.
- null** Production version of the silicon die that is fully qualified.

Production devices have been characterized fully, and the quality and reliability of the device have been demonstrated fully. TI's standard warranty applies.

Predictions show that prototype devices (X or P) have a greater failure rate than the standard production devices. Texas Instruments recommends that these devices not be used in any production system because their expected end-use failure rate still is undefined. Only qualified production devices are to be used.

TI device nomenclature also includes a suffix with the device family name. This suffix indicates the package type (for example, *RSM*).

For orderable part numbers of the CC2630 device in the *RSM*, *RHB* or *RGZ* package types, see the Package Option Addendum of this document, the TI website ([www.ti.com](http://www.ti.com)), or contact your TI sales representative.



**Figure 8-1. Device Nomenclature**

## 8.2 Tools and Software

TI offers an extensive line of development tools, including tools to evaluate the performance of the processors, generate code, develop algorithm implementations, and fully integrate and debug software and hardware modules.

The following products support development of the CC2630 device applications:

### Software Tools:

#### SmartRF Studio 7:

SmartRF Studio is a PC application that helps designers of radio systems to easily evaluate the RF-IC at an early stage in the design process.

- Test functions for sending and receiving radio packets, continuous wave transmit and receive
- Evaluate RF performance on custom boards by wiring it to a supported evaluation board or debugger
- Can also be used without any hardware, but then only to generate, edit and export radio configuration settings
- Can be used in combination with several development kits for Texas Instruments' CCxxxx RF-ICs

#### Sensor Controller Studio:

Sensor Controller Studio provides a development environment for the CC26xx Sensor Controller. The Sensor Controller is a proprietary, power-optimized CPU in the CC26xx, which can perform simple background tasks autonomously and independent of the System CPU state.

- Allows for Sensor Controller task algorithms to be implemented using a C-like programming language
- Outputs a Sensor Controller Interface driver, which incorporates the generated Sensor Controller machine code and associated definitions
- Allows for rapid development by using the integrated Sensor Controller task testing and debugging functionality. This allows for live visualization of sensor data and algorithm verification.

### IDEs and Compilers:

#### Code Composer Studio:

- Integrated development environment with project management tools and editor
- Code Composer Studio (CCS) 6.1 and later has built-in support for the CC26xx device family
- Best support for XDS debuggers; XDS100v3, XDS110 and XDS200
- High integration with TI-RTOS with support for TI-RTOS Object View

#### IAR Embedded Workbench for ARM

- Integrated development environment with project management tools and editor
- IAR EWARM 7.30.3 and later has built-in support for the CC26xx device family
- Broad debugger support, supporting XDS100v3, XDS200, IAR I-Jet and Segger J-Link
- Integrated development environment with project management tools and editor
- RTOS plugin available for [TI-RTOS](#)

For a complete listing of development-support tools for the CC2630 platform, visit the Texas Instruments website at [www.ti.com](http://www.ti.com). For information on pricing and availability, contact the nearest TI field sales office or authorized distributor.

### 8.3 Documentation Support

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com) (**CC2630**). In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

The current documentation that describes the CC2630 devices, related peripherals, and other technical collateral is listed in the following.

#### Technical Reference Manual

[CC13xx, CC26xx SimpleLink™ Wireless MCU Technical Reference Manual](#)

[CC26xx SimpleLink™ Wireless MCU Errata](#)

#### Errata

[CC2630 and CC2650 SimpleLink™ Wireless MCU Errata](#)

### 8.4 Texas Instruments Low-Power RF Website

Texas Instruments' Low-Power RF website has all the latest products, application and design notes, FAQ section, news and events updates. Go to [www.ti.com/lprf](http://www.ti.com/lprf).

### 8.5 Low-Power RF eNewsletter

The Low-Power RF eNewsletter is up-to-date on new products, news releases, developers' news, and other news and events associated with low-power RF products from TI. The Low-Power RF eNewsletter articles include links to get more online information.

Sign up at: [www.ti.com/lprfnewsletter](http://www.ti.com/lprfnewsletter)

### 8.6 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**TI Embedded Processors Wiki** *Texas Instruments Embedded Processors Wiki*. Established to help developers get started with Embedded Processors from Texas Instruments and to foster innovation and growth of general knowledge about the hardware and software surrounding these devices.

**Low-Power RF Online Community** Wireless Connectivity Section of the TI E2E Support Community

- Forums, videos, and blogs
- RF design help
- E2E interaction

Join [here](#).

**Low-Power RF Developer Network** Texas Instruments has launched an extensive network of low-power RF development partners to help customers speed up their application development. The network consists of recommended companies, RF consultants, and independent design houses that provide a series of hardware module products and design services, including:

- RF circuit, low-power RF, and ZigBee design services
- Low-power RF and ZigBee module solutions and development tools
- RF certification services and RF circuit manufacturing

For help with modules, engineering services or development tools:

Search the [Low-Power RF Developer Network](#) to find a suitable partner.  
[www.ti.com/lprfnetwork](http://www.ti.com/lprfnetwork)

## 8.7 Additional Information

Texas Instruments offers a wide selection of cost-effective, low-power RF solutions for proprietary and standard-based wireless applications for use in industrial and consumer applications. The selection includes RF transceivers, RF transmitters, RF front ends, and Systems-on-Chips as well as various software solutions for the sub-1-GHz and 2.4-GHz frequency bands.

In addition, Texas Instruments provides a large selection of support collateral such as development tools, technical documentation, reference designs, application expertise, customer support, third-party and university programs.

The Low-Power RF E2E Online Community provides technical support forums, videos and blogs, and the chance to interact with engineers from all over the world.

With a broad selection of product solutions, end-application possibilities, and a range of technical support, Texas Instruments offers the broadest low-power RF portfolio.

## 8.8 Trademarks

SimpleLink, SmartRF, Code Composer Studio, E2E are trademarks of Texas Instruments.

ARM7 is a trademark of ARM Limited (or its subsidiaries).

ARM, Cortex, ARM Thumb are registered trademarks of ARM Limited (or its subsidiaries).

CoreMark is a registered trademark of Embedded Microprocessor Benchmark Consortium.

IAR Embedded Workbench is a registered trademark of IAR Systems AB.

IEEE Std 1241 is a trademark of Institute of Electrical and Electronics Engineers, Incorporated.

ZigBee is a registered trademark of ZigBee Alliance, Inc.

All other trademarks are the property of their respective owners.

## 8.9 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 8.10 Export Control Notice

Recipient agrees to not knowingly export or re-export, directly or indirectly, any product or technical data (as defined by the U.S., EU, and other Export Administration Regulations) including software, or any controlled product restricted by other applicable national regulations, received from Disclosing party under this Agreement, or any direct product of such technology, to any destination to which such export or re-export is restricted or prohibited by U.S. or other applicable laws, without obtaining prior authorization from U.S. Department of Commerce and other competent Government authorities to the extent required by those laws.

## 8.11 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms and definitions.

# 9 Mechanical Packaging and Orderable Information

## 9.1 Packaging Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| CC2630F128RGZR   | ACTIVE        | VQFN         | RGZ                | 48   | 2500           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-3-260C-168 HR  | -40 to 85    | CC2630<br>F128          | <a href="#">Samples</a> |
| CC2630F128RGZT   | ACTIVE        | VQFN         | RGZ                | 48   | 250            | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-3-260C-168 HR  | -40 to 85    | CC2630<br>F128          | <a href="#">Samples</a> |
| CC2630F128RHBR   | ACTIVE        | VQFN         | RHB                | 32   | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-3-260C-168 HR  | -40 to 85    | CC2630<br>F128          | <a href="#">Samples</a> |
| CC2630F128RHBT   | ACTIVE        | VQFN         | RHB                | 32   | 250            | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-3-260C-168 HR  | -40 to 85    | CC2630<br>F128          | <a href="#">Samples</a> |
| CC2630F128RSMR   | ACTIVE        | VQFN         | RSM                | 32   | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-3-260C-168 HR  | -40 to 85    | CC2630<br>F128          | <a href="#">Samples</a> |
| CC2630F128RSMT   | ACTIVE        | VQFN         | RSM                | 32   | 250            | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-3-260C-168 HR  | -40 to 85    | CC2630<br>F128          | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| CC2630F128RGZR | VQFN         | RGZ             | 48   | 2500 | 330.0              | 16.4               | 7.3     | 7.3     | 1.1     | 12.0    | 16.0   | Q2            |
| CC2630F128RGZR | VQFN         | RGZ             | 48   | 2500 | 330.0              | 16.4               | 7.3     | 7.3     | 1.1     | 12.0    | 16.0   | Q2            |
| CC2630F128RGZT | VQFN         | RGZ             | 48   | 250  | 180.0              | 16.4               | 7.3     | 7.3     | 1.1     | 12.0    | 16.0   | Q2            |
| CC2630F128RGZT | VQFN         | RGZ             | 48   | 250  | 180.0              | 16.4               | 7.3     | 7.3     | 1.1     | 12.0    | 16.0   | Q2            |
| CC2630F128RHBR | VQFN         | RHB             | 32   | 3000 | 330.0              | 12.4               | 5.3     | 5.3     | 1.1     | 8.0     | 12.0   | Q2            |
| CC2630F128RHBR | VQFN         | RHB             | 32   | 3000 | 330.0              | 12.4               | 5.3     | 5.3     | 1.1     | 8.0     | 12.0   | Q2            |
| CC2630F128RHBT | VQFN         | RHB             | 32   | 250  | 180.0              | 12.4               | 5.3     | 5.3     | 1.1     | 8.0     | 12.0   | Q2            |
| CC2630F128RSMR | VQFN         | RSM             | 32   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |
| CC2630F128RSMR | VQFN         | RSM             | 32   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |
| CC2630F128RSMT | VQFN         | RSM             | 32   | 250  | 180.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |



## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CC2630F128RGZR | VQFN         | RGZ             | 48   | 2500 | 367.0       | 367.0      | 38.0        |
| CC2630F128RGZR | VQFN         | RGZ             | 48   | 2500 | 367.0       | 367.0      | 35.0        |
| CC2630F128RGZT | VQFN         | RGZ             | 48   | 250  | 210.0       | 185.0      | 35.0        |
| CC2630F128RGZT | VQFN         | RGZ             | 48   | 250  | 210.0       | 185.0      | 35.0        |
| CC2630F128RHBR | VQFN         | RHB             | 32   | 3000 | 346.0       | 346.0      | 33.0        |
| CC2630F128RHBR | VQFN         | RHB             | 32   | 3000 | 367.0       | 367.0      | 35.0        |
| CC2630F128RHBT | VQFN         | RHB             | 32   | 250  | 210.0       | 185.0      | 35.0        |
| CC2630F128RSMR | VQFN         | RSM             | 32   | 3000 | 367.0       | 367.0      | 35.0        |
| CC2630F128RSMR | VQFN         | RSM             | 32   | 3000 | 346.0       | 346.0      | 33.0        |
| CC2630F128RSMT | VQFN         | RSM             | 32   | 250  | 210.0       | 185.0      | 35.0        |

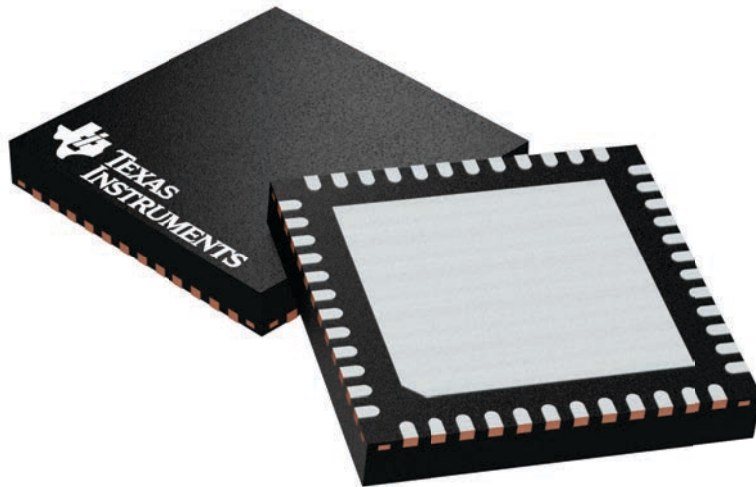
## GENERIC PACKAGE VIEW

**RGZ 48**

**VQFN - 1 mm max height**

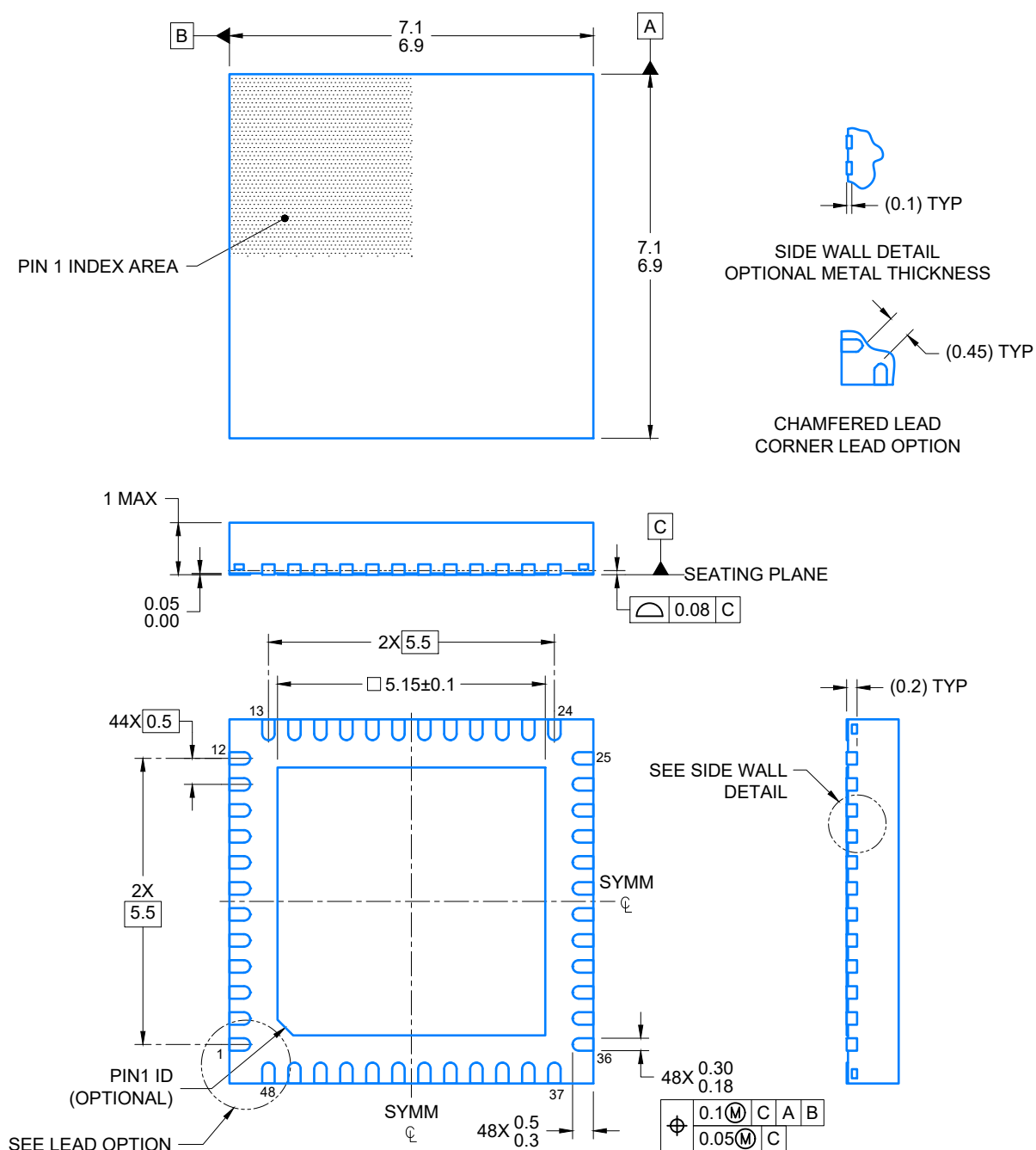
7 x 7, 0.5 mm pitch

PLASTIC QUADFLAT PACK- NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4224671/A

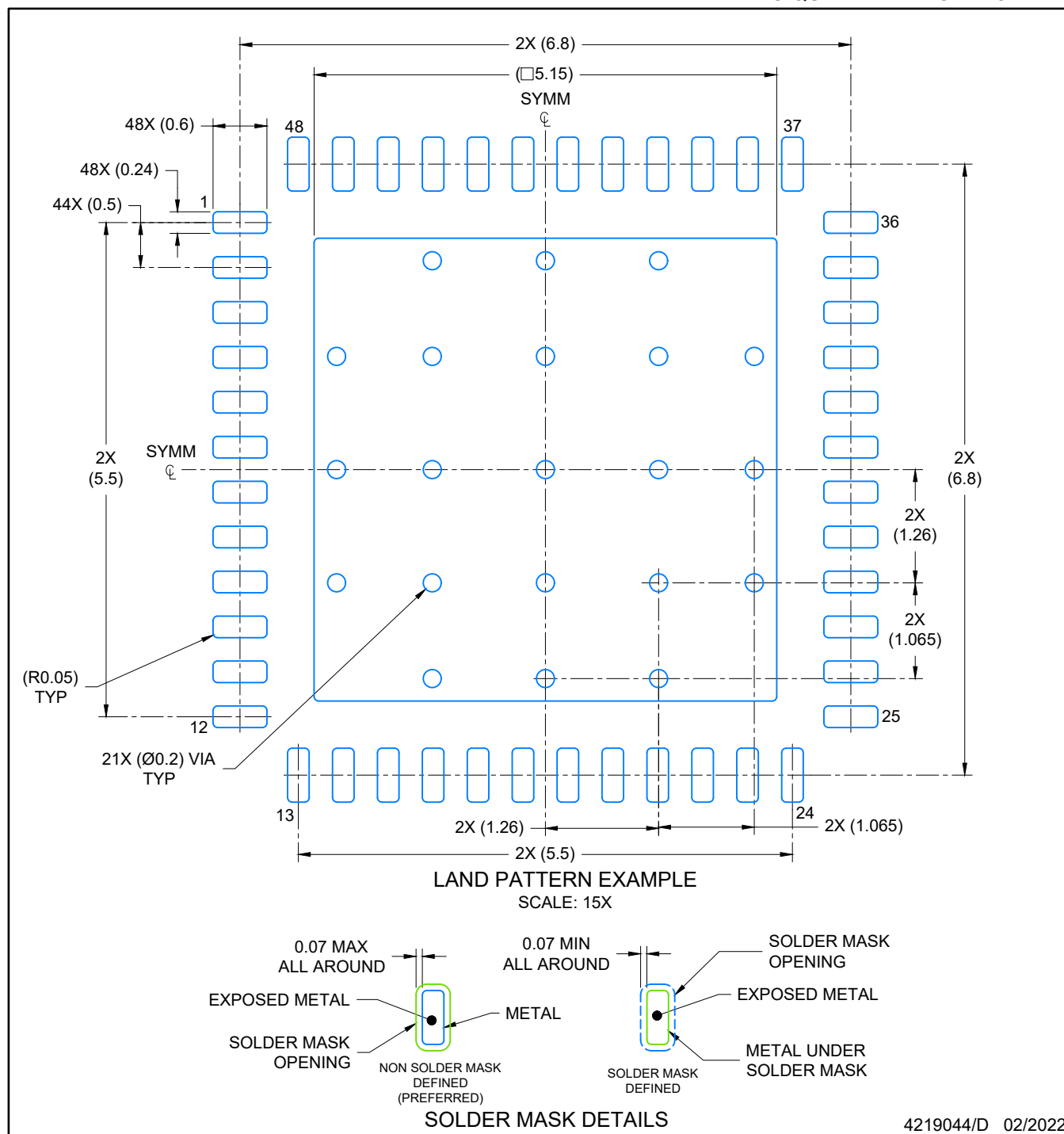


4219044/D 02/2022

NOTES:

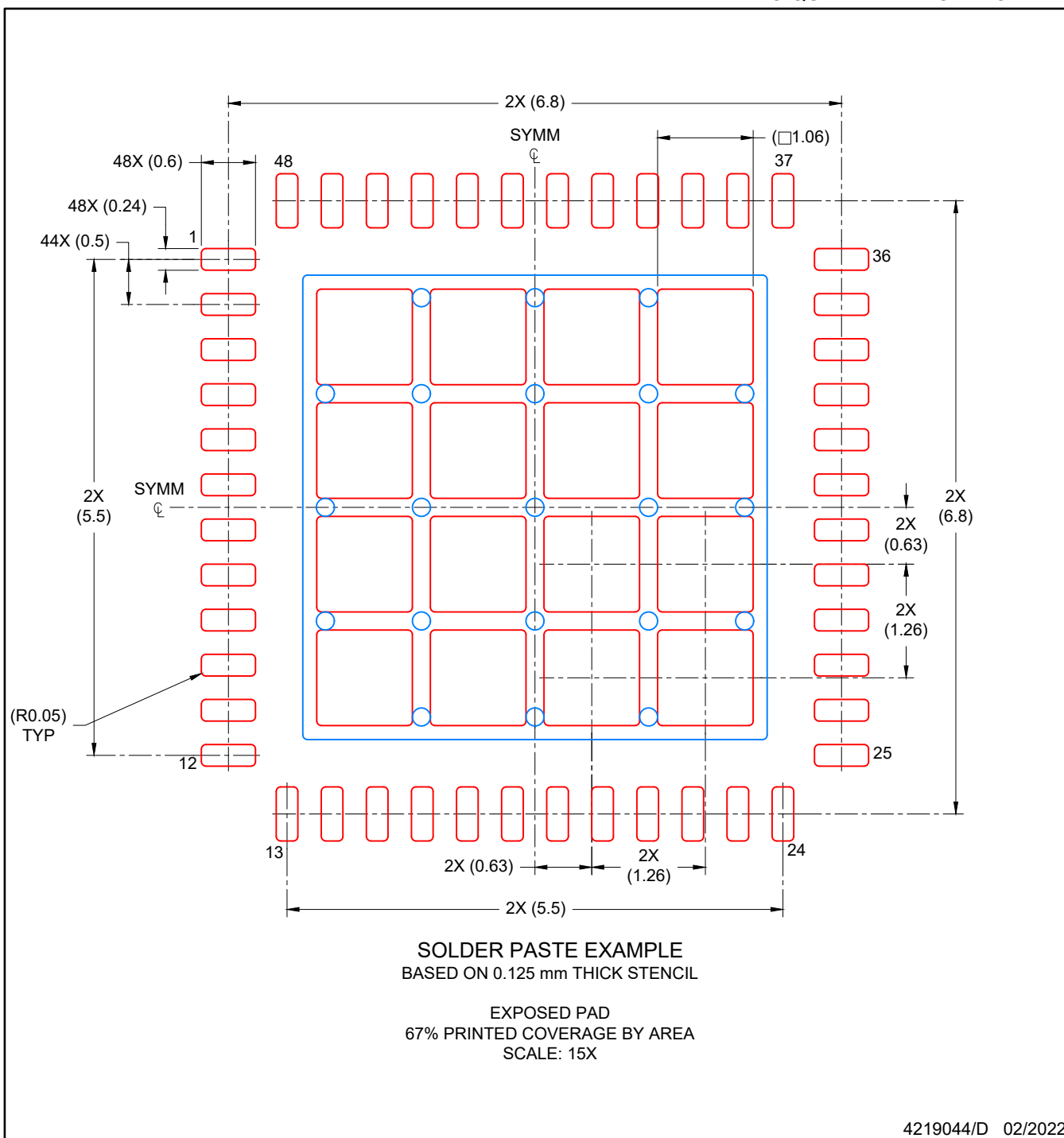
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

PLASTIC QUADFLAT PACK- NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

## GENERIC PACKAGE VIEW

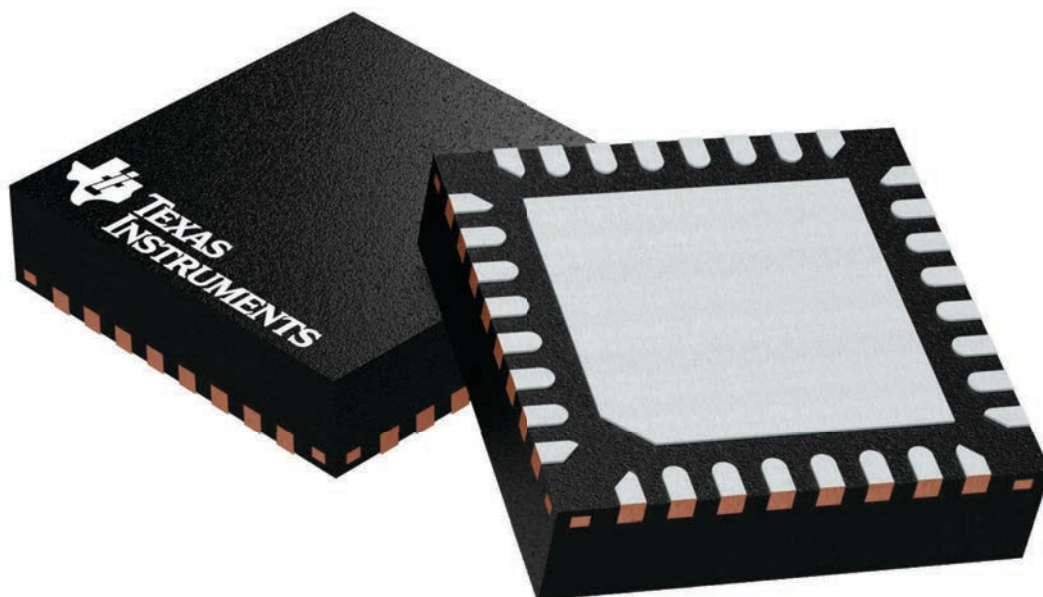
**RSM 32**

**VQFN - 1 mm max height**

4 x 4, 0.4 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224982/A



### VQFN - 1 mm max height

[illegible]

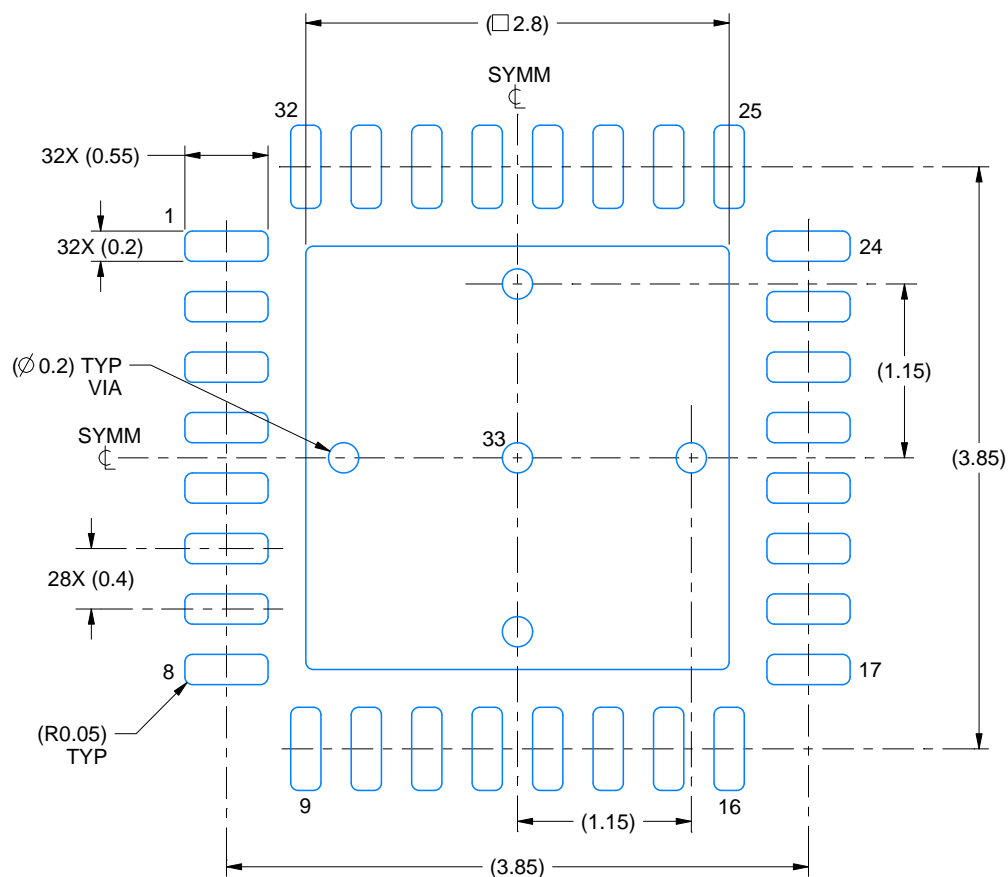
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

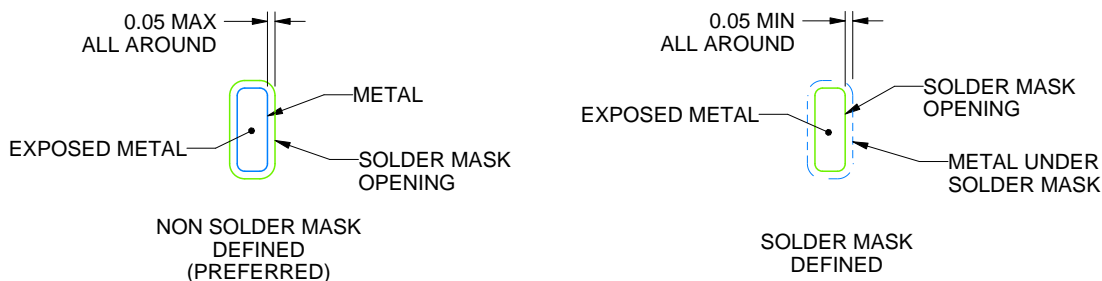
RSM0032B

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:20X



SOLDER MASK DETAILS

4219108/B 08/2019

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slue271](http://www.ti.com/lit/slue271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

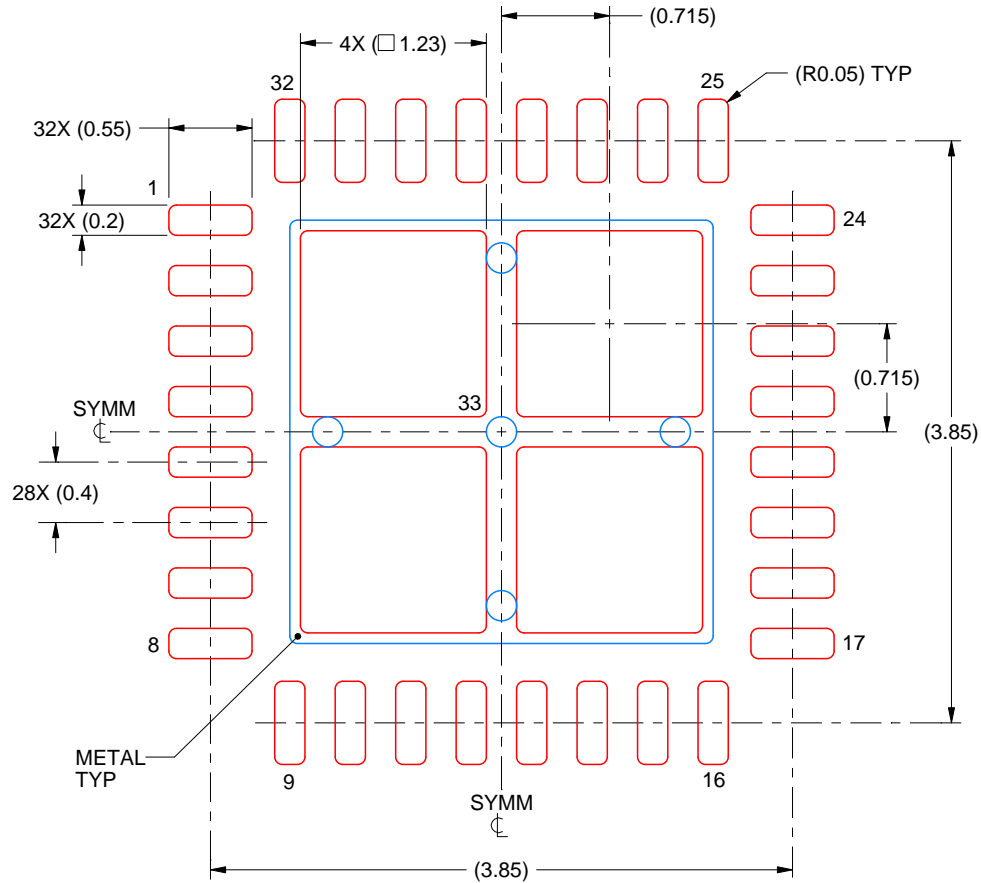


# EXAMPLE STENCIL DESIGN

RSM0032B

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



**SOLDER PASTE EXAMPLE**  
BASED ON 0.1 mm THICK STENCIL

EXPOSED PAD 33:  
77% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:20X

4219108/B 08/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

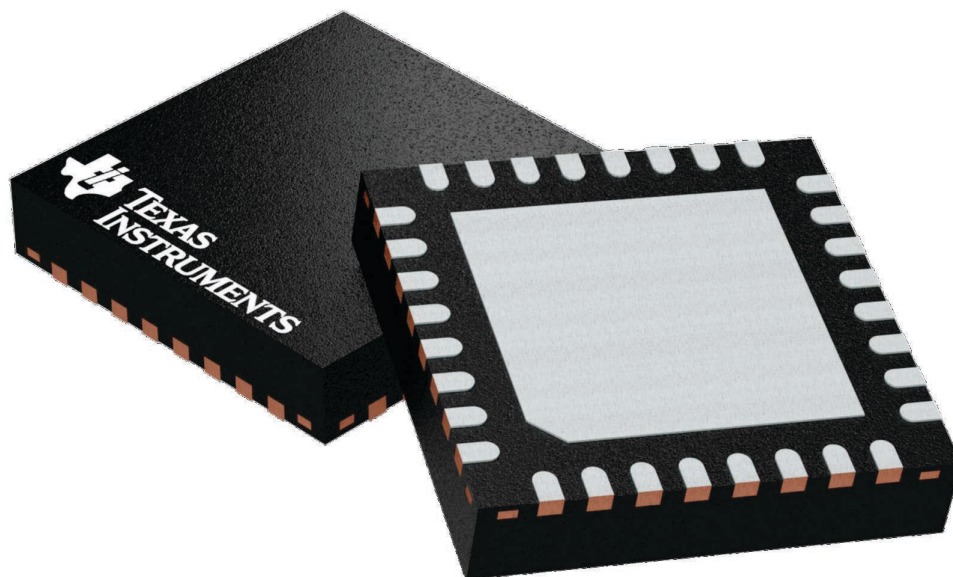
## GENERIC PACKAGE VIEW

**RHB 32**

**VQFN - 1 mm max height**

5 x 5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4224745/A

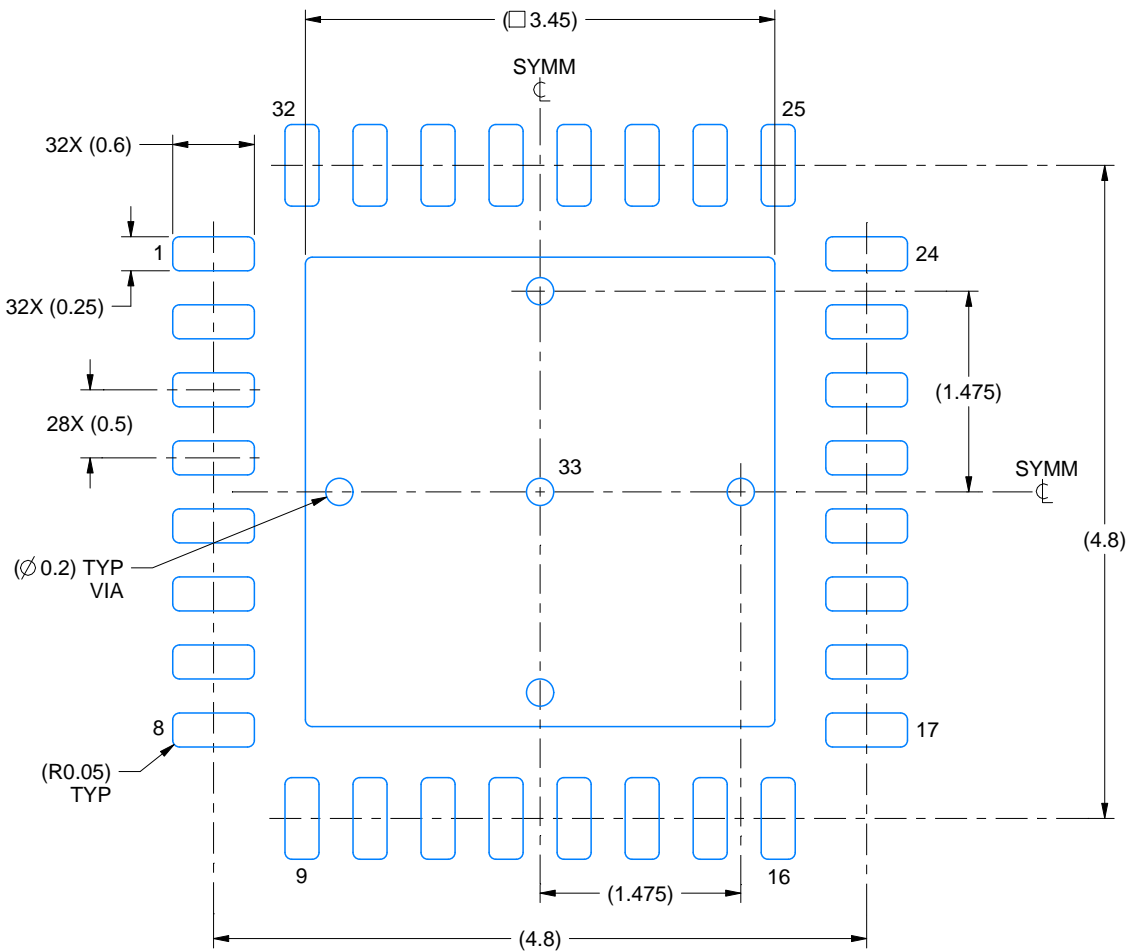
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

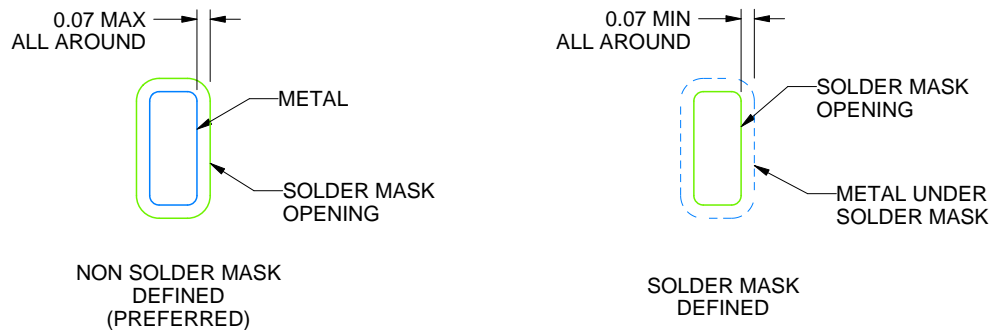
RHB0032E

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
SCALE:18X



SOLDER MASK DETAILS

4223442/B 08/2019

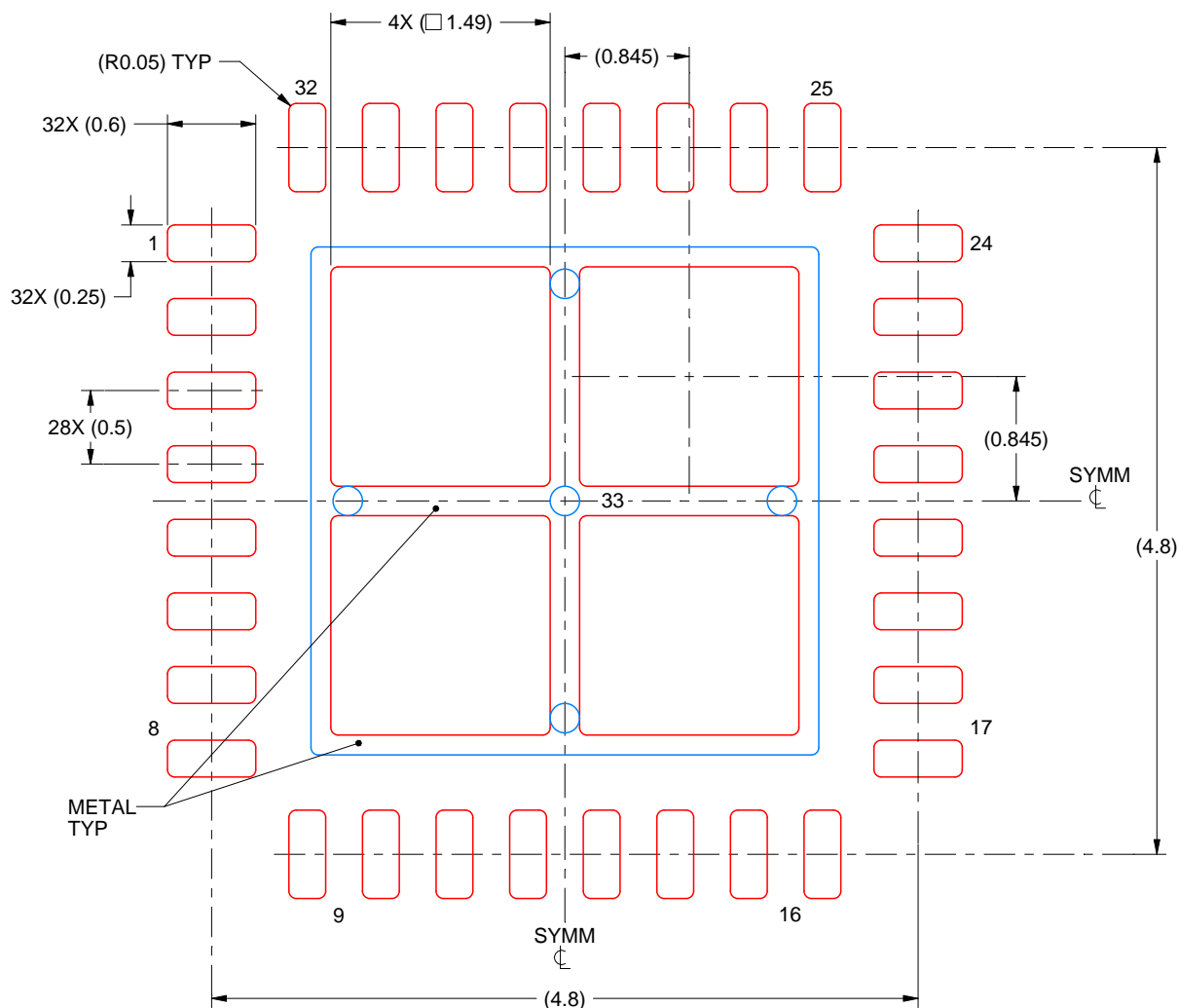
NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

**RHB0032E**

### VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



## SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 33:  
75% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:20X

4223442/B 08/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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